# Condensed Matter Physics <br> Part 2. Electronic System 

## Electrons in Solids

## - Quantum Mechanics of Electrons

## - Schrödinger Equation of Electron

An electron is a quantum particle described by the Schrödinger equation

$$
\begin{equation*}
\left(-\frac{\hbar^{2} \nabla^{2}}{2 m}+V(\boldsymbol{x})\right) \psi(\boldsymbol{x})=E \psi(\boldsymbol{x}) . \tag{1}
\end{equation*}
$$

- $m$ - electron mass,
- $V(\boldsymbol{x})$ - electronic potential at position $\boldsymbol{x}$,
- $\psi(\boldsymbol{x})$ - electron wave function (eigenstate), s.t. the probability (density) to observe an electron at position $\boldsymbol{x}$ is $|\psi(\boldsymbol{x})|^{2}$,
- $E$ - the corresponding eigen energy of the eigenstate.
- A Toy Atom in 1D

Consider an electron in 1D. An atomic nucleus (or a positively-charged ion) at the origin can be modeled by an attractive Dirac potential (with $-\gamma<0$ )

$$
\begin{equation*}
V(x)=-\gamma \delta(x), \tag{2}
\end{equation*}
$$



The Dirac potential viewed as the limit of square potential wells, where the potential is infinitely narrow and infinitely deep but keeps the width $\times$ depth $=\gamma$ constant. The constant $\gamma$ effectively describes the strength of the potential (which has to do with the nucleus charge etc.).

Schrödinger equation

$$
\begin{equation*}
-\frac{\hbar^{2}}{2 m} \partial_{x}^{2} \psi(x)-\gamma \delta(x) \psi(x)=E \psi(x) \tag{3}
\end{equation*}
$$

- Bound state $(E<0)$
- Wave function decays exponentially near the origin,

$$
\begin{equation*}
\psi(x)=\xi^{-1 / 2} e^{-|x| / \xi} \tag{4}
\end{equation*}
$$

with a decay length

$$
\begin{equation*}
\xi=\frac{\hbar^{2}}{m \gamma} \tag{5}
\end{equation*}
$$



In the bound state, the electron is trapped around the potential within the length scale $\xi . \Rightarrow$ The model mimics an atom (in 1D), where $\xi$ can be viewed as the atomic radius (Bohr radius).

- The eigen energy is negative (with respect to the potential zero)

$$
\begin{equation*}
E=-\frac{\hbar^{2}}{2 m \xi^{2}}=-\frac{m \gamma^{2}}{2 \hbar^{2}} \tag{6}
\end{equation*}
$$

- This is the unique bound state in the system, which is also the lowest-energy ground state of the electron.
- Scattering states $(E>0)$
- There are infinitely many scattering state solutions (forming a continuum in the spectrum).

Each scattering state is associated with an positive eigen energy $E>0$, which also sets a wave number
$k=\frac{\sqrt{2 m E}}{\hbar}$.

- Wave function
$\psi(x)=\left\{\begin{array}{ll}\boldsymbol{e}^{i k x}+A_{r} \boldsymbol{e}^{-i k x} & x<0 \\ A_{t} \boldsymbol{e}^{i k x} & x>0\end{array}\right.$,
with the reflection and transmission amplitudes

$$
\begin{align*}
& A_{r}=-\frac{1}{1+i k \xi}  \tag{16}\\
& A_{t}=\frac{1}{1-i /(k \xi)}
\end{align*}
$$



- In the scattering state, the electron has high enough energy to scatter off the potential. $\Rightarrow$ The atom ionize into dissociated electron and nucleus.
- In the following, we will be interested in bound states of electrons (in atomic orbitals), which are relevant to the solid state physics.


## - Two Toy Atoms in 1D

Place two nuclei from each other by distance $d$. An electron will experience two attractive Dirac potentials

$$
\begin{equation*}
V(x)=-\gamma \delta(x-d / 2)-\gamma \delta(x+d / 2) . \tag{17}
\end{equation*}
$$

Define the atomic radius

$$
\begin{equation*}
\xi=\frac{\hbar^{2}}{m \gamma} . \tag{18}
\end{equation*}
$$

- Bound state $(E<0)$ wave functions
- Even parity solution

$$
\psi(x)= \begin{cases}A \boldsymbol{e}^{\kappa x} & x<-d / 2,  \tag{19}\\ \cosh \kappa x & -d / 2<x<d / 2, \\ A \boldsymbol{e}^{-\kappa x} & x>d / 2\end{cases}
$$

- Odd parity solution

$$
\psi(x)= \begin{cases}-A e^{\kappa x} & x<-d / 2  \tag{20}\\ \sinh \kappa x & -d / 2<x<d / 2 \\ A e^{-\kappa x} & x>d / 2\end{cases}
$$

- The amplitude $A$ is given by (continuity of wave function)

$$
A= \begin{cases}\frac{1}{2}\left(e^{\kappa d}+1\right) & \text { even parity },  \tag{21}\\ \frac{1}{2}\left(e^{\kappa d}-1\right) & \text { odd parity }\end{cases}
$$

- Substitute Eq. (19), Eq. (20) into the Schrödinger equation, the imaginary wave number $\kappa$ is determined by

$$
e^{\kappa d}(\kappa \xi-1)= \begin{cases}+1 & \text { even parity },  \tag{22}\\ -1 & \text { odd parity },\end{cases}
$$

Exc
2
Derive Eq. (22).
The number of solutions of Eq. (22) depends on the inter-atomic distance $d$ and the atomic radius $\xi$,

- $d>\xi$ : two bound states of both parities,
- $d<\xi$ : one bound state of even parity.

$\square$ : even parity solution,
: odd parity solution.
- Based on the solutions of $\kappa$, the eigen energies are given by

$$
\begin{equation*}
E=-\frac{\hbar^{2} \kappa^{2}}{2 m} \tag{39}
\end{equation*}
$$



- The energy $E$ is plotted in unit of the ground state energy $E_{0}$ of a single atom given in Eq. (6)

$$
\begin{equation*}
E_{0}=-\frac{\hbar^{2}}{2 m \xi^{2}} \tag{40}
\end{equation*}
$$

- The even parity state is always the ground state of the two-atom system.
- Assuming electrons always occupy the ground state, as the atoms merge together (from $d \rightarrow \infty$ to $d \rightarrow 0$ ), the binding energy $E_{b}=E_{d \rightarrow \infty}-E_{d=0}=3\left|E_{0}\right|$ will be released (per electron).
- Force between atoms are given by

$$
\begin{equation*}
F=-\frac{\partial E}{\partial d} \tag{41}
\end{equation*}
$$

Inter-atomic force can be mediated by exchanging electron $\Rightarrow$ valence bond.

- Molecular orbitals of valence $\sigma$-bond

- Bonding orbital: electron in even parity state, atoms attract each other.
- Anti-bonding orbital: electron in odd parity state, atoms repel each other.


## - Tight Biding Approximation

Tight binding (atomic) limit: When the inter-atomic distance $d$ is sufficiently large compared to the atomic radius $\xi$ (i.e. $d \gg \xi$ ) $\Rightarrow$ the electron tightly binds the atomic nucleus, such that the molecular orbital can be approximated by superpositions of atomic orbitals.

## - Atomic orbitals

$$
\begin{align*}
& \langle x \mid 1\rangle=\psi_{1}(x)=\xi^{-1 / 2} e^{-\left|x-x_{1}\right| / \xi}, \\
& \langle x \mid 2\rangle=\psi_{2}(x)=\xi^{-1 / 2} e^{-\left|x-x_{2}\right| / \xi}, \tag{42}
\end{align*}
$$

where $x_{1}$ and $x_{2}$ are the positions of two nuclei respectively.

- $|1\rangle$ and $|2\rangle$ are not orthogonal, but close to orthogonal in the tight binding limit

$$
\begin{align*}
& \langle 1 \mid 2\rangle=\int_{-\infty}^{\infty} \psi_{1}^{*}(x) \psi_{2}(x) d x \\
& =\xi^{-1} \int_{-\infty}^{\infty} e^{-\left|x-x_{1}\right| / \xi} e^{-\left|x-x_{2}\right| / \xi} d x \tag{43}
\end{align*}
$$

$$
=\boldsymbol{e}^{-d / \xi}(1+d / \xi) \xrightarrow{d \gg} 0,
$$

where $d=\left|x_{1}-x_{2}\right|$.

- Tight binding basis: orthogonalized atomic orbitals

$$
\begin{equation*}
|\tilde{i}\rangle=\sum_{i} S_{i i}|i\rangle, \tag{44}
\end{equation*}
$$

such that

- The transformation matrix is given by

$$
S=\left(\begin{array}{ll}
S_{\tilde{1} 1} & S_{\tilde{1} 2}  \tag{45}\\
S_{\tilde{2} 1} & S_{\tilde{2} 2}
\end{array}\right)=\sqrt{\cosh 2 \varepsilon}\left(\begin{array}{cc}
\cosh \varepsilon & -\sinh \varepsilon \\
-\sinh \varepsilon & \cosh \varepsilon
\end{array}\right)
$$

where $\varepsilon$ is defined by

$$
\begin{equation*}
\tanh 2 \varepsilon=e^{-d / \xi}(1+d / \xi) . \tag{46}
\end{equation*}
$$

- $\varepsilon$ is expected to vanish in the tight biding limit. To the leading order in $\varepsilon$,
$|\tilde{1}\rangle \simeq|1\rangle-\varepsilon|2\rangle$,
$|\tilde{2}\rangle \simeq|2\rangle-\varepsilon|1\rangle$,
with $\varepsilon \simeq \frac{1}{2} e^{-d / \xi}(1+d / \xi)$.
- Hamiltonian operator

$$
\begin{align*}
H & =-\frac{\hbar^{2}}{2 m} \partial_{x}^{2}+V(x)  \tag{48}\\
& =-\frac{\hbar^{2}}{2 m} \partial_{x}^{2}-\gamma \delta\left(x-x_{1}\right)-\gamma \delta\left(x-x_{2}\right) .
\end{align*}
$$

It is assumed that $\gamma$ and $\xi$ are always related by $\xi=\hbar^{2} /(m \gamma)$, such that $|1\rangle$ and $|2\rangle$ are eigenstates of the Hamiltonian when only one potential is present, i.e.

$$
\begin{equation*}
\left(-\frac{\hbar^{2}}{2 m} \partial_{x}^{2}-\gamma \delta\left(x-x_{i}\right)\right) \psi_{i}(x)=E_{0} \psi_{i}(x), \tag{49}
\end{equation*}
$$

with the atomic orbital eigen energy

$$
\begin{equation*}
E_{0}=-\frac{\hbar^{2}}{2 m \xi^{2}} \tag{50}
\end{equation*}
$$

- Tight binding Hamiltonian: the effective Hamiltonian in the tight binding basis

$$
\begin{equation*}
H_{\mathrm{eff}}=\sum_{i, j=1,2}|\tilde{i}\rangle \tilde{H}_{i j}\langle\tilde{j}|, \tag{51}
\end{equation*}
$$

where $\tilde{H}_{i j} \equiv\langle\tilde{i}| H|\tilde{j}\rangle$.

- The matrix element $\tilde{H}_{i j}$ can be obtained from

$$
\begin{align*}
& H_{i j} \equiv\langle i| H|j\rangle \\
& =\int_{-\infty}^{\infty} \psi_{i}^{*}(x)\left(-\frac{\hbar^{2}}{2 m} \partial_{x}^{2}-\gamma \delta\left(x-x_{1}\right)-\gamma \delta\left(x-x_{2}\right)\right) \psi_{j}(x) d x, \tag{52}
\end{align*}
$$

via basis transformation Eq. (44)

$$
\begin{equation*}
\tilde{H}_{i j}=\sum_{i j} S_{i i} H_{i j} S_{\tilde{j} j}, \tag{53}
\end{equation*}
$$

or written in terms of matrix multiplication $\tilde{H}=S H S^{\mathrm{T}}$.

- Substitute Eq. (42) into Eq. (52), one finds

$$
H=\left(\begin{array}{ll}
H_{11} & H_{12}  \tag{54}\\
H_{21} & H_{22}
\end{array}\right)=E_{0}\left(\begin{array}{cc}
1+2 e^{-2 d / \xi \xi} & e^{-d / \xi}(3+d / \xi) \\
e^{-d / \xi}(3+d / \xi) & 1+2 e^{-2 d / \xi}
\end{array}\right),
$$

where $E_{0}$ is the atomic orbital energy.
Derive Eq. (54).

- Substitute Eq. (45) and Eq. (54) into Eq. (53), to the leading order of $\boldsymbol{e}^{-d / \xi}$ (in the tight binding limit), the effective Hamiltonian reads

$$
\begin{align*}
& \tilde{H}=S H S^{\mathrm{T}} \\
& =E_{0}\left(\begin{array}{cc}
1 & 2 e^{-d / \xi} \\
2 e^{-d / \xi} & 1
\end{array}\right)+O\left(e^{-2 d / \xi}\right) . \tag{60}
\end{align*}
$$

or written in the tight binding basis as

$$
\begin{equation*}
H_{\mathrm{eff}}=E_{0}(|\tilde{1}\rangle\langle\tilde{1}|+|\tilde{2}\rangle\langle\tilde{2}|)+2 E_{0} e^{-d / \xi}(|\tilde{1}\rangle\langle\tilde{2}|+|\tilde{2}\rangle\langle\tilde{1}|) . \tag{61}
\end{equation*}
$$

- The diagonal term $|\tilde{1}\rangle\langle\tilde{1}|+|\tilde{2}\rangle\langle\tilde{2}|$ describes that the electron trapped around an atom will experience the on-site energy $E_{0}$.
- The off-diagonal term $|\tilde{1}\rangle\langle\tilde{2}|+|\tilde{2}\rangle\langle\tilde{1}|$ describes that the electron can tunnel from one atom to another, and the process is associated with an energy scale $2 E_{0} e^{-d / \xi}$, which is also called the hopping energy.
- Molecular orbitals (tight binding model)
- In the tight biding basis, the Schrödinger equation reduces from a differential equation to a matrix equation
$H_{\text {eff }}|\psi\rangle=E|\psi\rangle$,
or explicitly

$$
E_{0}\left(\begin{array}{cc}
1 & 2 e^{-d / \xi}  \tag{63}\\
2 \boldsymbol{e}^{-d / \xi} & 1
\end{array}\right)\binom{\psi_{\tilde{1}}}{\psi_{\tilde{2}}}=E\binom{\psi_{\tilde{1}}}{\psi_{\tilde{2}}} .
$$

- Solving the eigen problem, one finds two eigen states with the eigen energy $E_{ \pm}$

$$
\begin{align*}
& E_{ \pm}=E_{0}\left(1 \pm 2 e^{-d / \xi}\right), \\
& \left|\psi_{ \pm}\right\rangle=\frac{1}{\sqrt{2}}(|\tilde{1}\rangle \pm|\tilde{2}\rangle) \propto|1\rangle \pm|2\rangle . \tag{64}
\end{align*}
$$



-     - Solid curve: exact energy.
- Dashed curve: approximate energy to the 1 st order in $\boldsymbol{e}^{-d / \xi}$ (given by the tight binding model).
- $\square$ : even parity, bonding orbital $\left|\psi_{+}\right\rangle$,
$\square$ : odd parity, anti-bonding orbital $\left|\psi_{-}\right\rangle$


## - 1D Electronic Systems

## - Electron on 1D Lattice

A electron moving on the background of a lattice of positive ions.

$$
\begin{equation*}
H=-\frac{\hbar^{2}}{2 m} \partial_{x}^{2}+V(x) \tag{65}
\end{equation*}
$$

- Periodic potential: $V(x+a)=V(x)$, i.e. the potential is invariant under lattice translation $x \rightarrow x+a$.


Define a set of tight binding basis

$$
\begin{equation*}
\langle x \mid i\rangle=\psi_{i}(x) \propto \boldsymbol{e}^{-\left|x-x_{i}\right| / \xi}+(\text { orthogonality corrections } \ldots), \tag{66}
\end{equation*}
$$

where $x_{i}=i a$ is the position of the $i$ th ion ( $i$ - site index, labels the lattice site).


- The lattice translation correspond to $|i\rangle \rightarrow|i+1\rangle$ for tight binding basis.

Expand the Hamiltonian $H$ on the tight binding basis,

$$
\begin{equation*}
H=\sum_{i j}|i\rangle H_{i j}\langle j|, \tag{67}
\end{equation*}
$$

where $H_{i j} \equiv\langle i| H|j\rangle$.

- The lattice translation symmetry implies

$$
\begin{equation*}
\langle i+1| H|j+1\rangle=\langle i| H|j\rangle, \tag{68}
\end{equation*}
$$

i.e. $H_{i j}$ only depends on the index difference $i-j$.

- Hermiticity of the Hamiltonian requires

$$
\begin{equation*}
H_{i j}=H_{j i}^{*} . \tag{69}
\end{equation*}
$$

- The Hamiltonian matrix must take the form of

$$
H_{i j}= \begin{cases}-t_{i-j} & i>j  \tag{70}\\ \epsilon_{0} & i==j, \\ -t_{j-i}^{*} & i<j\end{cases}
$$

or in the matrix form as

$$
H=\left(\begin{array}{ccccc}
\ddots & \ddots & \ddots & & \ddots  \tag{71}\\
\ddots & \epsilon_{0} & -t_{1}^{*} & -t_{2}^{*} & \\
\ddots & -t_{1} & \epsilon_{0} & -t_{1}^{*} & \ddots \\
& -t_{2} & -t_{1} & \epsilon_{0} & \ddots \\
\ddots & & \ddots & \ddots & \ddots
\end{array}\right) .
$$

- $\epsilon_{0}$ - on-site potential energy.
- $t_{n}-n$th neighbor hopping parameter (kinetic energy). $t_{n}$ is expected to decay exponentially
$t_{n} \sim \boldsymbol{e}^{-\left|x_{n}-x_{0}\right| / \xi}=\boldsymbol{e}^{-n a / \xi}$,
therefore $t_{n}$ is often truncated to the first few leading ones (the few nearest neighbors hopping parameters).


## - Tight Binding Model and Energy Band

Truncate to 2 nd nearest neighbor hopping. Assuming $t_{1}, t_{2} \in \mathbb{R}$, the tight binding Hamiltonian reads

$$
\begin{equation*}
H=\epsilon_{0} \sum_{i}|i\rangle\langle i|-t_{1} \sum_{i}(|i+1\rangle\langle i|+\text { h.c. })-t_{2} \sum_{i}(|i+2\rangle\langle i|+\text { h.c. }), \tag{73}
\end{equation*}
$$

where h.c. stands for the omitted term related by Hermitian conjugation.
Goal: solve the Schrödinger equation , find the eigen states and the corresponding eigen energies of the electron.

It turns out that the Hamiltonian can be simply diagonalized by transforming to the quasimomentum basis

- The quasi-momentum basis and the tight binding basis are related Fourier / inverse Fourier transforms

$$
\begin{align*}
& |i\rangle=N^{-1 / 2} \sum_{k} e^{-i k x_{i}}|k\rangle, \\
& |k\rangle=N^{-1 / 2} \sum_{i} e^{i k x_{i}}|i\rangle, \tag{74}
\end{align*}
$$

where $N$ is the total number of sites in the lattice.

- Assuming $N$ is even, $\sum_{k}$ sums over

$$
\begin{equation*}
k=0, \pm \frac{2 \pi}{N a}, \ldots, \pm \frac{2 \pi m}{N a}, \ldots, \pm \frac{2 \pi(N / 2-1)}{N a}, \frac{\pi}{a} \tag{75}
\end{equation*}
$$

- $\sum_{i}$ sums over $i=1,2, \ldots, N-1, N$.
- Substitute Eq. (74) into Eq. (73), the Hamiltonian is diagonalized

$$
\begin{aligned}
H & =\sum_{k} \epsilon_{k}|k\rangle\langle k|, \\
\epsilon_{k} & =\epsilon_{0}-2 t_{1} \cos (k a)-2 t_{2} \cos (2 k a) .
\end{aligned}
$$

## Exc 4 Derive Eq. (76).

- Dispersion relation $\epsilon_{k}$ of the electron (also called band structure, band dispersion)

- The dispersion relation $\epsilon_{k}$ is periodic in the quasi-momentum, i.e.

$$
\begin{equation*}
\epsilon_{k+\frac{2 \pi}{a}}=\epsilon_{k}, \tag{79}
\end{equation*}
$$

so the quasi-momentum $k$ of electron can be taken to be in the first Brillouin zone $k \in(-\pi / a, \pi / a]$.

- Energy band: the allowed energy range of the electron. The electron can not take an energy outside the energy band (as there is no state outside the energy band for the electron to occupied).
- Eigenstates (quasi-momentum basis states) in real space representation

$$
\begin{align*}
& \langle x \mid k\rangle=N^{-1 / 2} \sum_{i} e^{i k x_{i}}\langle x \mid i\rangle \\
& =N^{-1 / 2} \sum_{i} e^{i k a i} \psi_{i}(x) . \tag{80}
\end{align*}
$$

Tight binding basis $\psi_{i}$ enveloped by a plane wave.


- Group velocity of the electron

$$
\begin{equation*}
v_{k}=\frac{1}{\hbar} \frac{\partial \epsilon_{k}}{\partial k} . \tag{81}
\end{equation*}
$$

Take the dispersion relation $\epsilon_{k}$ in Eq. (76),

$$
\begin{equation*}
v_{k}=\frac{2 a t_{1}}{\hbar} \sin (k a)+\frac{4 a t_{2}}{\hbar} \sin (2 k a) . \tag{82}
\end{equation*}
$$



- The group velocity always vanishes $\left(v_{k}=0\right)$ at both the Brillouin zone center $(k=0)$ and zone boundary ( $k=\pi / a$ ), because they are inversion symmetric points (i.e. $k \cong-k$ ) in the Brillouin zone. Since velocity is odd under inversion
$v_{-k}=-v_{k}$,
it must vanish at inversion symmetric momentum points.
- The quasi-momentum basis states $|k\rangle$ are standing wave states at $k=0$ and $k=\pi / a$, i.e. the electron wave does not propagate and the group velocity vanishes. The standing wave at $k=\pi / a$ is caused by the strong back-scattering (Bragg scattering) of electron by the lattice.
- Effective mass $m_{\text {eff }}$ of the electron

$$
\begin{equation*}
m_{\mathrm{eff}}^{-1}=\frac{1}{\hbar} \frac{\partial v_{k}}{\partial k}=\frac{1}{\hbar^{2}} \frac{\partial^{2} \epsilon_{k}}{\partial k^{2}} . \tag{84}
\end{equation*}
$$

Take the dispersion relation $\epsilon_{k}$ in Eq. (76),

$$
\begin{equation*}
m_{\text {eff }}^{-1}=\frac{2 a^{2} t_{1}}{\hbar^{2}} \cos (k a)+\frac{8 a^{2} t_{2}}{\hbar^{2}} \cos (2 k a) \tag{85}
\end{equation*}
$$

- At band bottom $(k=0)$, the effective mass is positive

$$
\begin{equation*}
m_{\mathrm{eff}}=\frac{\hbar^{2}}{2 a^{2}\left(t_{1}+4 t_{2}\right)} \tag{86}
\end{equation*}
$$

- At band top, the effective mass is negative. For example, for $t_{2}<t_{1} / 4$, the band top is at $k=\pi / a$, where the effective mass is

$$
\begin{equation*}
m_{\mathrm{eff}}=\frac{\hbar^{2}}{2 a^{2}\left(-t_{1}+4 t_{2}\right)} \tag{87}
\end{equation*}
$$

When the effective mass is negative, the electron velocity decreases with increasing momentum. The negative effective mass is a peculiar feature of electron on the lattice.

## - Thermodynamic Limit and Density of State

The total number $N$ of lattice sites was introduced to regularize the Fourier transform. However, the physical results (intensive properties of the system) should have be well-defined in the thermodynamic limit $N \rightarrow \infty$.

In particular, the momentum summation can be replaced by a momentum integration in the thermodynamic limit $N \rightarrow \infty$, as the momentum grid spacing $2 \pi /(N a) \rightarrow 0$,

$$
\begin{equation*}
\sum_{k}=N a \int_{-\pi}^{\pi} \frac{d k}{2 \pi}=V \int_{-\pi}^{\pi} \frac{d k}{2 \pi} \tag{88}
\end{equation*}
$$

where $V=N a$ is the (1D) volume of the system.

- Extensive property that involves summation $\sum_{k}$ of states will be proportional to the volume $V$.
- Intensive property (extensive property per volume) eliminates the volume dependence, and has well-defined thermodynamic limit.

The momentum integration can be further converted to an energy integration,

$$
\begin{equation*}
\sum_{k}=V \int d \epsilon \sum_{\epsilon_{k}=\epsilon} \frac{1}{2 \pi \partial_{k} \epsilon_{k}}=V \int d \epsilon \sum_{\epsilon_{k}=\epsilon} \frac{1}{2 \pi \hbar v_{k}} . \tag{89}
\end{equation*}
$$

Define the density of state $g(\epsilon)$ via

$$
\begin{equation*}
\sum_{k}=V \int d \epsilon g(\epsilon) . \tag{90}
\end{equation*}
$$

For 1D system,

$$
\begin{equation*}
g(\epsilon)=\sum_{\epsilon_{k}=\epsilon} \frac{1}{2 \pi \hbar v_{k}} . \tag{91}
\end{equation*}
$$

- For $\epsilon_{k}=-2 t \cos (k a)$, we have $\hbar v_{k}=2 a t \sin (k a)$,

$$
\begin{align*}
& g(\epsilon)=\sum_{-2 t \cos (k a)=\epsilon} \frac{1}{4 \pi a t \sin (k a)} \\
& =\frac{1}{2 \pi a t \sin \left(\arccos \frac{\epsilon}{2 t}\right)}  \tag{92}\\
& =\frac{1}{\pi a \sqrt{(2 t)^{2}-\epsilon^{2}}} \text {. }
\end{align*}
$$

$$
\begin{aligned}
& \epsilon
\end{aligned}
$$

- The divergences of density of state near band edges are examples of van Hove singularities.
- The mid-band density of state saturates to $g(0)=1 /(2 \pi a t)$.

Consider adding a stagger potential $u$ to the 1D tight biding model (assuming the nearest neighboring bond length to be 1 , as the length unit)
$H=-t \sum_{i}(|i+1\rangle\langle i|+$ h.c. $)-u \sum_{i}(-1)^{i}|i\rangle\langle i|$.
For $u \neq 0$, the primitive unit cell is enlarged from one site to two sites. The first Brillouin zone correspondingly shrinks to $[\pi / 2,-\pi / 2)$.
(i) How many bands do you expect?
(ii) Calculate the band dispersion for each band.

By diagonalizing the electron Hamiltonian, we have just solved a single-particle problem, and obtained the eigenstates that an electron can occupied. When there is many electrons in the system, each eigenstate of the eigenenergy $\epsilon$ will have an occupation probability given by the Fermi-Dirac distribution

$$
\begin{equation*}
n_{F}(\epsilon)=\frac{1}{e^{\beta(\epsilon-\mu)}+1}, \tag{93}
\end{equation*}
$$

- $\beta=1 / k_{B} T$, where $T$ is the temperature.
- $\mu$ is the chemical potential (Fermi energy).

- The chemical potential is set by the total number $N_{e}$ of electrons

$$
\begin{equation*}
N_{e}=2 \sum_{k} n_{F}\left(\epsilon_{k}\right)=2 \sum_{k} \frac{1}{e^{\beta\left(\epsilon_{k}-\mu\right)}+1} . \tag{94}
\end{equation*}
$$

The factor 2 in front of the summation takes into account the fact that each electron has two degenerated spin states.

- Then the total internal energy $E$ of the electronic system is

$$
\begin{equation*}
E=2 \sum_{k} \epsilon_{k} n_{F}\left(\epsilon_{k}\right)=2 \sum_{k} \frac{\epsilon_{k}}{e^{\beta\left(\epsilon_{k}-\mu\right)}+1} . \tag{95}
\end{equation*}
$$

In the low-temperature $(T \rightarrow 0)$ limit, electrons will simply occupy all states below the Fermi energy $\mu$, such that Eq. (94) and Eq. (95) simplifies to

$$
\begin{equation*}
N_{e}=2 \sum_{\epsilon_{k}<\mu} 1, E=2 \sum_{\epsilon_{k}<\mu} \epsilon_{k} . \tag{96}
\end{equation*}
$$

- For $\epsilon_{k}=-2 t \cos (k a)$, use the density of state $g(\epsilon)$ in Eq. (92), the total number of electrons increases with $\mu$ from 0 to 2 as

$$
N_{e}=2 V \int_{-2 t}^{\mu} d \epsilon g(\epsilon)
$$

$$
\begin{array}{rl}
= & \frac{2 V}{\pi a} \int_{-2 t}^{\mu} d \epsilon \frac{1}{\sqrt{(2 t)^{2}-\epsilon^{2}}} \\
= & \frac{2 N}{\pi}\left(\arcsin \left(\frac{\mu}{2 t}\right)+\frac{\pi}{2}\right) . \\
& 2.0 \\
z^{2} & 1.5 \\
& 0.0
\end{array}
$$

and the total internal energy varies with $\mu$ as

$$
\begin{align*}
& E=2 V \int_{-2}^{\mu} d \epsilon \epsilon g(\epsilon) \\
& =\frac{2 V}{\pi a} \int_{-2 t}^{\mu} d \epsilon \frac{\epsilon}{\sqrt{(2 t)^{2}-\epsilon^{2}}}  \tag{98}\\
& =-\frac{2 N}{\pi} \sqrt{(2 t)^{2}-\mu^{2}} \text {. }
\end{align*}
$$

- Filling fraction: the fraction of a energy band filled by electrons

$$
\begin{equation*}
v=\frac{N_{e}}{2 N} \tag{99}
\end{equation*}
$$

where $2 N$ is the number of states (including 2-fold spin degeneracy) in the energy band. $N$ is the number of sites in the lattice.

- When $0<v<1$, the many-body system of electrons forms a metal (in the non-interacting limit).

- In the many-body ground state: electrons occupy all states from the band bottom up to the designated filling fraction $\Rightarrow$ total energy $E$ is minimized.
- A current-carrying excited state can be created by an imbalanced occupation of electrons, such that there are more electrons on the $v_{k}>0$ side than those on the $v_{k}<0$ side. $\Rightarrow$ $\langle j\rangle=e \sum_{k}\left\langle v_{k}\right\rangle \neq 0 . \Rightarrow$ Metal can conduct electricity.
- However, if the band if empty $(v=0)$ or fully filled $(v=1)$, the current-carrying state can not be constructed. $\Rightarrow$ The system can not conduct electricity, hence an insulator (also called band insulator).

$$
v=0,\langle j\rangle=0 \quad v=1,\langle j\rangle=0
$$



- Metallic bond: $N$ atoms can gain energy jointly by allowing their electrons to delocalize and hybridize across the whole system. This energy gain binds all atoms together forming a metallic state.

- Given $\epsilon_{k}$, one can calculate $E$ v.s. $N_{e}$ by tuning $\mu$ in Eq. (96).
- The total energy $E$ is typically minimized at a some $v \in(0,1) \Rightarrow$ electrons forming a metallic state.


## - Su-Schrieffer-Heeger Model

The Su-Schrieffer-Heeger (SSH) model is the simplest model of symmetry protected topological (SPT) state of electrons. It describes electrons in a poly-acetylene structure


- Each unit cell (gray shaded) now contains two atoms (labeled by $A$ and $B$ ). Each lattice site is labeled jointly by the unit cell index $i$ and the sublatice label $A / B$, such that a set of tight binding basis can be defined

$$
\begin{equation*}
\ldots,|i, A\rangle,|i, B\rangle,|i+1, A\rangle,|i+1, B\rangle \ldots \tag{100}
\end{equation*}
$$

- The hopping parameters are different on the double bond and the single bond (double bond is shorter $\Rightarrow$ larger hopping).
- $v$ : intra-unit-cell hopping,
- w: inter-unit-cell hopping.



## The tight binding Hamiltonian:

$$
\begin{equation*}
H=-v \sum_{i}(|i, B\rangle\langle i, A|+\text { h.c. })-w \sum_{i}(|i+1, A\rangle\langle i, B|+\text { h.c. }) \tag{101}
\end{equation*}
$$

Assuming periodic boundary condition, the system respect lattice translation symmetry, such that the quasi-momentum is a good quantum number. The Hamiltonian can be diagonalized by transforming to the quasi-momentum basis (defined separately on each sublattice)

$$
\begin{align*}
& |k, A\rangle=N^{-1 / 2} \sum_{i} e^{i k x_{i}}|i, A\rangle, \\
& |k, B\rangle=N^{-1 / 2} \sum_{i} e^{i k x_{i}}|i, B\rangle, \tag{102}
\end{align*}
$$

where $x_{i}=i$ (with unit cell size set to $a=1$ ), and $N$ is the number of unit cells on the lattice. The inverse transformation is given by

$$
\begin{align*}
& |i, A\rangle=N^{-1 / 2} \sum_{k} e^{-i k x_{i}}|k, A\rangle, \\
& |i, B\rangle=N^{-1 / 2} \sum_{k} e^{-i k x_{i}}|k, B\rangle, \tag{103}
\end{align*}
$$

where $\sum_{k}$ sums over $k \in(-\pi, \pi]$ in the first Brillouin zone with momentum step size $2 \pi / N$.
The Hamiltonian in Eq. (101) becomes

$$
\begin{align*}
& H=\sum_{k}\left(f_{k}|k, B\rangle\langle k, A|+f_{k}^{*}|k, A\rangle\langle k, B|\right),  \tag{104}\\
& f_{k}=-v-w \boldsymbol{e}^{i k} .
\end{align*}
$$

Exc
5
Derive Eq. (104).

- Represent in the $\{|k, A\rangle,|k, B\rangle\}$ basis, $H$ takes the matrix form

$$
H \bumpeq \bigoplus_{k} H_{k}, H_{k} \simeq\left(\begin{array}{cc}
0 & f_{k}^{*}  \tag{106}\\
f_{k} & 0
\end{array}\right),
$$

No mixing between different momentum sectors $\Rightarrow$ the Hamiltonian can be diagonalized in each momentum sector independently.

- Goal: find eigen vectors

$$
\begin{align*}
& |k, m\rangle=u_{k, m, A}|k, A\rangle+u_{k, m, B}|k, B\rangle \\
& =\binom{u_{k, m, A}}{u_{k, m, B}} . \tag{107}
\end{align*}
$$

such that

$$
\begin{equation*}
H_{k}|k, m\rangle=\epsilon_{k, m}|k, m\rangle, \tag{108}
\end{equation*}
$$

or more explicitly

$$
\left(\begin{array}{cc}
0 & f_{k}^{*}  \tag{109}\\
f_{k} & 0
\end{array}\right)\binom{u_{k, m, A}}{u_{k, m, B}}=\epsilon_{k, m}\binom{u_{k, m, A}}{u_{k, m, B}} .
$$

## Eigen energies $\Rightarrow$ band dispersion

$$
\begin{equation*}
\epsilon_{k, \pm}= \pm\left|f_{k}\right|= \pm \sqrt{v^{2}+w^{2}+2 v w \cos k} \tag{110}
\end{equation*}
$$



- There are two bands (labeled by $\pm$ ), matching the number of sites in the unit cell.
- Band gap: the range of energy between two bands. Electrons are forbidden to appear in the band gap (there is no state for the electron to occupy within the gap).
- Band gap opens at the Brillouin zone boundary, with the gap size

$$
\begin{equation*}
2 \Delta=2|v-w| . \tag{111}
\end{equation*}
$$

- In the low-temperature $(T \rightarrow 0)$ limit, electrons will fully occupy the lower band, forming a band insulator.

- The band structure does not distinguish $v>w$ from $v<w$, more information is contained in the eigenstates.

Eigenstates corresponding to $\epsilon_{k, \pm}$, represented as two-component state vectors in the $\{|k, A\rangle,|k, B\rangle\}$ basis

$$
\begin{equation*}
|k, \pm\rangle \bumpeq \frac{1}{\sqrt{2}}\binom{1}{ \pm f_{k} /\left|f_{k}\right|} \tag{112}
\end{equation*}
$$

- $f_{k} /\left|f_{k}\right| \in \mathrm{U}(1) \cong S^{1}$ is a phase factor, that can wind around as $k \in S^{1}$ cycles over the first Brillouin zone.
- The map $f: S^{1} \rightarrow S^{1}$ is classified by the homotopy group $\pi_{1}\left(S^{1}\right) \cong \mathbb{Z}$. Distinct homotopy classes are indexed by different winding number

$$
\begin{equation*}
\omega=\frac{1}{2 \pi i} \int_{-\pi}^{\pi} d k \partial_{k} \ln f_{k} . \tag{113}
\end{equation*}
$$

- $v>w$ (intra $>$ inter): $\omega=0$ (trivial insulator),
- $v<w$ (intra $<$ inter): $\omega=1$ (topological insulator).

- A topological phase transition happens at $v=w$, where the system transition between the trivial insulator and the topological insulator, via gap closing and reopening.

More generally, the winding number can be defined for a vector bundle $|k, \pm\rangle$ over the Brillouin zone

$$
\begin{align*}
& \omega_{ \pm}=\frac{1}{2 \pi} \int_{-\pi}^{\pi} d k \mathcal{A}_{k, \pm},  \tag{114}\\
& \mathcal{A}_{k, \pm}=-i\langle k, \pm| \partial_{k}|k, \pm\rangle,
\end{align*}
$$

- $\mathcal{A}_{k, \pm}$ is the Berry connection of the vector bundle,
- $2 \pi \omega_{ \pm}$is the Berry phase accumulated along the Brillouin zone cycle, which is also called the Zak phase for the 1D case.

Topological edge mode. When $v<w$ (topological), there is a zero-energy dangling electron mode on each end of the chain (altogether two edge modes on both ends).


They can be observe in the spectrum. Put the tight binding Hamiltonian H Eq. (101) on a open chain (open boundary condition). The lattice translation symmetry is broken by the open ends, the quasi-momentum is no longer a good quantum number. One should diagonalize the Hamiltonian directly in tight binding basis Eq. (100)

$$
H \bumpeq\left(\begin{array}{ccccc}
0 & v & & &  \tag{115}\\
v & 0 & w & & \\
& w & \ddots & \ddots & \\
& & \ddots & \ddots & v \\
& & & v & 0
\end{array}\right) .
$$

- Energy spectrum:

- When $v<w$ (topological), two zero-energy modes are left in the energy gap.
- Edge states (zero-energy model): assuming the states take the form of

$$
\begin{equation*}
|L / R\rangle=\sum_{i}\left(u_{i, A}^{L / R}|i, A\rangle+u_{i, B}^{L / R}|i, B\rangle\right) . \tag{116}
\end{equation*}
$$

The wave amplitude $u_{i, A / B}^{ \pm}$( $\square$ on $A$ sublattice, $\square$ on $B$ sublattice) are plotted for both zero modes:


- The wave amplitude decays exponentially from the edge with an localization length $\xi$, e.g.

$$
\begin{equation*}
\left|u_{i, A}^{ \pm}\right| \sim e^{-x_{i} / \xi} . \tag{117}
\end{equation*}
$$

Summary:

| parameters | $v>w$ | $v<w$ |
| :---: | :---: | :---: |
| phase | trivial insulator | topological insulator |
| winding number | 0 | 1 |
| dimmerization | intra-unit-cell | inter-unit-cell |
| edge mode | no | yes (one/edge) |
| ground state deg. | 1 | 2 (fix filling) |

(i) Determine the edge mode localization length $\xi$ as a function of hopping parameters HW $\quad v$ and $w$ in the SSH model (assuming $w>v>0$ ).
2
(ii) Show that near the critical point $v-w \rightarrow 0_{-}$, the localization length $\xi$ is inversely proportional to the band gap $\Delta=|v-w|$.

## - Chiral Symmetry

Question: No matter how we tune $v, w$, the energy spectrum is always symmetric with respect to $E \rightarrow-E$, why?

- Sublattice projection operators

$$
\begin{align*}
P_{A} & =\sum_{i}|i, A\rangle\langle i, A|, \\
P_{B} & =\sum_{i}|i, B\rangle\langle i, B| . \tag{118}
\end{align*}
$$

- For any state $|\psi\rangle$ of an electron,
$\langle\psi| P_{A}|\psi\rangle=$ probability to find the electron on sublattice $A$,
$\langle\psi| P_{B}|\psi\rangle=$ probability to find the electron on sublattice $B$.


## - Chiral operator

$$
\begin{equation*}
S=P_{A}-P_{B}=\sum_{i}(|i, A\rangle\langle i, A|-|i, B\rangle\langle i, B|), \tag{119}
\end{equation*}
$$

or, in the momentum space,

$$
\begin{equation*}
S=\sum_{k}(|k, A\rangle\langle k, A|-|k, B\rangle\langle k, B|), \tag{120}
\end{equation*}
$$

Represent in the $\{|k, A\rangle,|k, B\rangle\}$ basis, $S$ takes the matrix form

$$
S \bumpeq \bigoplus_{k} S_{k}, S_{k} \bumpeq\left(\begin{array}{cc}
1 & 0  \tag{121}\\
0 & -1
\end{array}\right)=\sigma^{3} .
$$

## - Under chiral transformation

$$
\left\{\begin{array} { l } 
{ S | i , A \rangle = | i , A \rangle , }  \tag{122}\\
{ S | i , B \rangle = - | i , B \rangle . }
\end{array} \quad \left\{\begin{array}{l}
S_{k}|k, A\rangle=|k, A\rangle, \\
S_{k}|k, B\rangle=-|k, B\rangle .
\end{array}\right.\right.
$$

$B$ sublattice state gets a minus sign.

- The chiral transformation forms a $\mathbb{Z}_{2}$ group, as $S^{2}=1$ (where 1 stands for the identity operator).
- For any state $|\psi\rangle$ of an electron, $\langle\psi| S|\psi\rangle=$ sublattice polarization.

Such that
$\langle\psi| S|\psi\rangle>0$ : more likely to find the electron on sublattice $A$,
$\langle\psi| S|\psi\rangle<0$ : more likely to find the electron on sublattice $B$.

- Chiral symmetry: a unitary symmetry that anti-commutes with the Hamiltonian.

$$
\begin{equation*}
S H S=-H, \tag{123}
\end{equation*}
$$

or, in the momentum space,

$$
\begin{equation*}
\forall k: S_{k} H_{k} S_{k}=-H_{k} . \tag{124}
\end{equation*}
$$

## Exc

$6 \quad$ Check Eq. (123) and Eq. (124).
Using the property $S^{2}=1$, Eq. (123) is equivalent to $S H=-H S$.
Spectral consequence of chiral symmetry: Let $\left|\psi_{n}\right\rangle$ be any eigenstate of $H$ with eigen energy $E_{n}$, s.t.

$$
\begin{equation*}
H\left|\psi_{n}\right\rangle=E_{n}\left|\psi_{n}\right\rangle . \tag{127}
\end{equation*}
$$

Chiral symmetry implies

$$
\begin{equation*}
H S\left|\psi_{n}\right\rangle=-S H\left|\psi_{n}\right\rangle=-S\left(E_{n}\left|\psi_{n}\right\rangle\right)=-E_{n} S\left|\psi_{n}\right\rangle, \tag{128}
\end{equation*}
$$

meaning that $S\left|\psi_{n}\right\rangle$ is also an eigenstate of $H$ but of an opposite eigen energy $-E_{n}$.

- If $E_{n} \neq 0,\left|\psi_{n}\right\rangle$ and $S\left|\psi_{n}\right\rangle$ are two distinct eigenstate of $H$ with opposite eigen energies $E_{n}$ and - $E_{n} \Rightarrow$ finite energy eigenstates always comes in $\pm E_{n}$ pairs.
- For example, in the momentum space, $H_{k}|k, \pm\rangle=\epsilon_{k, \pm}|k, \pm\rangle$, the eigen states indeed comes in pairs, related by the chiral transformation,
$S_{k}|k, \pm\rangle=|k, \mp\rangle$,
and the corresponding eigen energies are opposite to each other $\epsilon_{k, \pm}= \pm\left|f_{k}\right|$.
- However, even when the lattice translation symmetry is broken (e.g. on an open chain or in the presence of disorder) that quasi-momentum is not well-defined, the pairing of positive and negative energy states still holds through out the spectrum.
- If $E_{n}=0,\left|\psi_{n}\right\rangle$ and $S\left|\psi_{n}\right\rangle$ are both zero-energy eigenstates of $H$, but they could be the same state. So there is no requirement for the zero energy states to come in pairs.
Sublattice polarization. The chiral symmetry $S H=-H S$ implies

$$
\begin{align*}
& \left\langle\psi_{n}\right| H S\left|\psi_{n}\right\rangle=-\left\langle\psi_{n}\right| S H\left|\psi_{n}\right\rangle \\
& \Rightarrow E_{n}\left\langle\psi_{n}\right| S\left|\psi_{n}\right\rangle=-E_{n}\left\langle\psi_{n}\right| S\left|\psi_{n}\right\rangle  \tag{130}\\
& \Rightarrow 2 E_{n}\left\langle\psi_{n}\right| S\left|\psi_{n}\right\rangle=0 .
\end{align*}
$$

- If $E_{n} \neq 0$, then $\left\langle\psi_{n}\right| S\left|\psi_{n}\right\rangle=0$, i.e. sublattice polarization should vanish for any finite energy eigenstate (the electron must appear on sublattice $A$ and $B$ with equal probability).
- This statement is manifest for momentum space eigenstates

$$
\begin{equation*}
|k, \pm\rangle=\frac{1}{\sqrt{2}}\left(|k, A\rangle \pm \frac{f_{k}}{\left|f_{k}\right|}|k, B\rangle\right) . \tag{131}
\end{equation*}
$$

- If $E_{n}=0$, there is no restriction on $\left\langle\psi_{n}\right| S\left|\psi_{n}\right\rangle$. In fact, one can choose $\left|\psi_{n}\right\rangle$ to be the common eigenstate of $S$ and $H$ (as they commute in the zero-energy sector). Given that $S$ only has two eigenvalues $\pm 1$, the zero-energy eigenstates can all be classified by

$$
\begin{equation*}
\left\langle\psi_{n}\right| S\left|\psi_{n}\right\rangle= \pm 1 \tag{132}
\end{equation*}
$$

i.e. the electron in zero-energy state is either fully polarized to sublattice $A$ or to sublattice $B$.

- The topological edge states are such examples.


## - Topological Phases of Band Insulators

Definition of topological phases for band insulators:

- (No symmetry)* Two band insulator Hamiltonians $H$ and $H^{\prime}$ are in the same (invertible) topological phases, if they can be deformed into each other without closing the band gap. * strictly speaking, band insulators already assumes the $\mathrm{U}(1)$ symmetry that corresponds to the electron number conservation. So "no symmetry" here means no additional symmetry apart form $U(1)$.
- (With symmetry) Two band insulator Hamiltonians $H$ and $H^{\prime}$ are in the same symmetry protected topological (SPT) phases, if they can be deformed into each other without closing the band gap and without breaking the symmetry.

Assuming lattice translation symmetry, the most general Hamiltonian for 1D electronic system with two-site unit cell takes the form of

$$
\begin{equation*}
H \bumpeq \bigoplus_{k} H_{k}, H_{k} \bumpeq h_{\mu}(k) \sigma^{\mu}, \tag{133}
\end{equation*}
$$

- As a $2 \times 2$ Hermitian matrix, $H_{k}$ can always be decomposed to real combinations of Pauli matrices $\sigma^{\mu}$

$$
\sigma^{0}=\left(\begin{array}{ll}
1 & 0  \tag{134}\\
0 & 1
\end{array}\right), \sigma^{1}=\left(\begin{array}{ll}
0 & 1 \\
1 & 0
\end{array}\right), \sigma^{2}=\left(\begin{array}{cc}
0 & -i \\
i & 0
\end{array}\right), \sigma^{3}=\left(\begin{array}{cc}
1 & 0 \\
0 & -1
\end{array}\right),
$$

with the combination coefficients $h_{\mu}(k) \in \mathbb{R}(\mu=0,1,2,3)$.

- For example, the SSH model:

$$
\begin{equation*}
h_{0}(k)=0, h_{1}(k)=\operatorname{Re} f_{k}, h_{2}(k)=\operatorname{Im} f_{k}, h_{3}(k)=0 . \tag{135}
\end{equation*}
$$

- Deforming $H$ is to deform the $h_{\mu}(k)$ functions, subject to the periodic condition $h_{\mu}(k+2 \pi)=h_{\mu}(k)\left(\right.$ i.e. $\left.k \in S^{1}\right)$.
The eigen energies of $H_{k}$ is given by

$$
\begin{equation*}
\epsilon_{k, \pm}=h_{0}(k) \pm|\boldsymbol{h}(k)|, \tag{136}
\end{equation*}
$$

where $\boldsymbol{h}(k)=\left(h_{1}(k), h_{2}(k), h_{3}(k)\right)$ and $|\boldsymbol{h}(k)|=\sqrt{\boldsymbol{h}(k) \cdot \boldsymbol{h}(k)}$.

- Gapping condition. To maintain the band gap is to keep the vector $\boldsymbol{h}(k)$ finite length everywhere in the Brillouin zone

$$
\begin{align*}
\forall k & :|\boldsymbol{h}(k)|>0 .  \tag{137}\\
\text { or } \boldsymbol{h}(k) & \in \mathbb{R}^{3} \backslash\{\mathbf{0}\} .
\end{align*}
$$

- Deformation without symmetry. All smooth deformations of the map $\boldsymbol{h}: S^{1} \rightarrow \mathbb{R}^{3} \backslash\{\mathbf{0}\}$ are classified by the homotopy group

$$
\begin{equation*}
\pi_{1}\left(\mathbb{R}^{3} \backslash\{\mathbf{0}\}\right) \cong \pi_{1}\left(S^{2}\right) \cong 0 \tag{138}
\end{equation*}
$$

which is a trivial group, meaning that all maps $\boldsymbol{h}$ can be deformed into each other $\Rightarrow$ Without additional symmetry (other than $\mathrm{U}(1)$ ), all insulators in 1D are in the same phase (the trivial phase).

The chiral symmetry imposes additional constrains on the Hamiltonian.

$$
\begin{equation*}
\forall k: S_{k} H_{k} S_{k}=-H_{k}, \tag{139}
\end{equation*}
$$

given $S_{k}=\sigma^{3}$, which requires

$$
\begin{equation*}
h_{0}(k)=h_{3}(k)=0 . \tag{140}
\end{equation*}
$$

\section*{| Exc | Derive Eq. (140) from Eq. (139), given Eq. (133). |
| :---: | :--- |
| $\mathbf{7}$ | (1) |}

In the presence of the chiral symmetry, $\boldsymbol{h}(k)$ is restricted to the $h_{1}-h_{2}$ plane (excluding the origin), i.e. $\boldsymbol{h}(k) \in \mathbb{R}^{2} \backslash\{\mathbf{0}\}$.

- Deformation under the chiral symmetry. All smooth deformation of the map $\boldsymbol{h}: S^{1} \rightarrow \mathbb{R}^{2} \backslash\{\mathbf{0}\}$ are classified by the homotopy group

$$
\begin{equation*}
\pi_{1}\left(\mathbb{R}^{2} \backslash\{\mathbf{0}\}\right) \cong \pi_{1}\left(S^{1}\right) \cong \mathbb{Z} \tag{144}
\end{equation*}
$$

which is the integer addition group. Each class is labeled by an integer topological index $\omega$, which corresponds to the winding number of $\boldsymbol{h}$ around the origin in the $h_{1}-h_{2}$ plane.

- Protected by the chiral symmetry, it is not possible to smoothly deform 1D insulators of different topological indices $\Rightarrow$ topological insulators $(\omega \neq 0)$ and the trivial insulator $(\omega=0)$ must be separated by gap-closing topological phase transitions.
- However, if the chiral symmetry is broken, the symmetry protection is lifted, and it becomes possible to smoothly deforming among all 1D insulators.

In the SSH model, the chiral symmetry can be broken by adding a stagger potential term $u$

$$
\begin{equation*}
H=-v \sum_{i}(|i, B\rangle\langle i, A|+\text { h.c. })-w \sum_{i}(|i+1, A\rangle\langle i, B|+\text { h.c. })-u \sum_{i}(|i, A\rangle\langle i, A|-|i, B\rangle\langle i, B|) . \tag{145}
\end{equation*}
$$

Correspondingly, the momentum space Hamiltonian becomes

$$
H \simeq \bigoplus_{k} H_{k}, H_{k} \bumpeq\left(\begin{array}{cc}
u & f_{k}^{*}  \tag{146}\\
f_{k} & -u
\end{array}\right)=\operatorname{Re} f_{k} \sigma^{1}+\operatorname{Im} f_{k} \sigma^{2}+u \sigma^{3},
$$

- The energy dispersion becomes
$\epsilon_{k, \pm}= \pm \sqrt{\left|f_{k}\right|^{2}+u^{2}}=\sqrt{v^{2}+w^{2}+2 v w \cos k+u^{2}}$.
$(v, w, u)=(1.5,0.5,0)$

- Phase diagram. With the chiral symmetry, $u=0$, the trivial and topological phases must be separated by phase transitions. However, when the chiral symmetry is broken by $u \neq 0$, the topological transitions can be avoided / circumvented.

- Protected by the chiral symmetry, topological edge mode must exist on the boundary (the interface between trivial and topological states), otherwise one can proliferate the featureless boundary to avoid bulk transition (which contradict with the definition of SPT phases).

- Interaction reduced classification. The band homotopy classification indicates that 1D band insulators with charge conservation and chiral symmetries are $\mathbb{Z}$-classified. However, this is not the full story when interaction is taken into account. The stable classification is $\mathbb{Z}_{4}$ for 1D interacting fermionic SPT states in symmetry class AIII, meaning that the $\omega=4$ insulator can be trivialized by interaction. [1]
[1] Lukasz Fidkowski, Alexei Kitaev. The effects of interactions on the topological classification of free fermion systems. arXiv:0904.2197.


## - 2D Electronic Systems

## - Electron on Square Lattice

Consider an electron hopping on a 2D square lattice (as in cuprate superconductors).

$$
\boldsymbol{x}_{i}=n_{i, 1} \boldsymbol{a}_{1}+n_{i, 2} \boldsymbol{a}_{2},\left\{\begin{array}{l}
\boldsymbol{a}_{1}=(1,0)  \tag{148}\\
\boldsymbol{a}_{2}=(0,1)
\end{array}\right.
$$

where $n_{i, 1}, n_{i, 2} \in \mathbb{Z}$.


- Define the nearest neighboring bond vectors (the vector that point from one site to its nearest neighboring site)

$$
\left\{\begin{array}{l}
\boldsymbol{\delta}_{1}=\boldsymbol{a}_{1}=(1,0)  \tag{149}\\
\boldsymbol{\delta}_{2}=\boldsymbol{a}_{2}=(0,1) \\
\boldsymbol{\delta}_{3}=-\boldsymbol{a}_{1}=(-1,0) \\
\boldsymbol{\delta}_{4}=-\boldsymbol{a}_{2}=(0,-1)
\end{array} .\right.
$$

Tight binding Hamiltonian (nearest neighbor hopping)

$$
\begin{equation*}
H=-t \sum_{\langle i j\rangle}(|i\rangle\langle j|+\text { h.c. }) . \tag{150}
\end{equation*}
$$

- $i, j$ are site indices, which also label the tight binding basis $|i\rangle$.
- $\langle i j\rangle$ denotes $i, j$ are adjacent on the lattice. $\sum_{\langle i j\rangle}$ sums over all such nearest neighbor links.

Switch to the quasi-momentum basis,

$$
\begin{align*}
& |\boldsymbol{k}\rangle=N^{-1 / 2} \sum_{i} e^{i \boldsymbol{k} \cdot \boldsymbol{x}_{i}}|i\rangle \\
& |i\rangle=N^{-1 / 2} \sum_{k} e^{-i \boldsymbol{k} \cdot \boldsymbol{x}_{i}}|\boldsymbol{k}\rangle . \tag{151}
\end{align*}
$$

- $N=L_{x} \times L_{y}$ is the total number of unit cells (sites). $L_{x}, L_{y}$ are the (linear) size of the lattice along $x$ and $y$ directions.
- $\sum_{k}$ sums over momentum $\boldsymbol{k}$ in the first Brillouin zone $(-\pi, \pi]^{\times 2}$ on a grid with spacings $2 \pi / L_{x}$ and $2 \pi / L_{y}$ along $x$ and $y$ directions.
The Hamiltonian Eq. (150) is diagonalized in the quasi-momentum basis

$$
H=\sum_{k} \epsilon_{k}|\boldsymbol{k}\rangle\langle\boldsymbol{k}|
$$

$$
\epsilon_{k}=-t \sum_{a} e^{i \boldsymbol{k} \cdot \boldsymbol{\delta}_{a}}=-2 t\left(\cos \boldsymbol{k} \cdot \boldsymbol{a}_{1}+\cos \boldsymbol{k} \cdot \boldsymbol{a}_{2}\right) .
$$

## Exc <br> 8 Derive Eq. (152).

Band dispersion $\epsilon_{k}$ in the first Brillouin zone.


- High symmetry points of the Brillouin zone: $\Gamma(0,0), X(\pi, 0), Y(0, \pi), M(\pi, \pi)$.
- The band structure is often represented by plotting $\epsilon_{k}$ along straight line segments connecting high symmetry points.


The electron will fill up the band up to the Fermi surface. Let $v$ be the filling fraction, and $\epsilon_{\mathrm{F}}$ be the Fermi energy,

$$
\begin{equation*}
v=\frac{\sum_{k \in \mathrm{BZ}} \Theta\left(\epsilon_{\mathrm{F}}-\epsilon_{k}\right)}{\sum_{k \in \mathrm{BZ}} 1}, \tag{156}
\end{equation*}
$$

the filling fraction is the fraction that the Fermi sea takes up in the Brillouin zone.


- Symmetry and the general shape of Fermi surface. In the free space, electrons should have a circular Fermi surface, due to the $\mathrm{SO}(2)$ rotation symmetry. However, on a lattice, the full $\mathrm{SO}(2)$ rotation symmetry is broken to its discrete subgroup, such as $\mathbb{Z}_{4}$ for the square lattice. So the Fermi surface only have four-fold symmetry on a square lattice.
- Small Fermi surface remains circular. Because electrons are also waves, when the wave length is much larger than the lattice spacing (which is the case near the $\Gamma$ point), the electron will not resolve the lattice structure (as the structure is below the diffraction limit of the electron wave), and will not experience the symmetry breaking effect caused by the lattice, hence the Fermi surface remains circular near the $\Gamma$ point.
- Expand the dispersion relation $\epsilon_{k}$ in Eq. (152) around the $\Gamma$ point $(\boldsymbol{k} \rightarrow 0)$ (here the lattice constant $a=1$ has been restored)

$$
\begin{gather*}
\epsilon_{k}=-4 t+t a^{2} \boldsymbol{k}^{2}+O\left(k^{4}\right) \\
=-4 t+\frac{\hbar^{2} \boldsymbol{k}^{2}}{2 m_{\mathrm{eff}}}+O\left(k^{4}\right) \tag{157}
\end{gather*}
$$

with the effective mass $m_{\text {eff }}=\hbar^{2} /\left(2 t a^{2}\right)$ of the electron set by the hopping parameter $t$, similar to Eq. (86).

- Large Fermi surface can be distorted. As the Fermi surface approaches the Brillouin zone boundary, the lattice scattering effect gets more prominent, which distorts the Fermi surface to non-circular shape (such as the square shape at half filling).
- "Broken" Fermi surface. Beyond half filling, the Fermi surface can even touch the Brillouin zone boundary.
- Note that whenever a Fermi surface touches the zone boundary, it must do so perpendicularly, because the normal component of the group velocity must be zero at the zone boundary.
- The Fermi surface seems to be broken into segments, however, it is actually still continuous since the Brillouin zone is periodic.
- Electron v.s. hole Fermi surface. When the filling fraction approaches one, the Fermi surface looks circular again (if we look at the empty region). It can be viewed as filling full band with holes. Holes are anti-particles of electrons. High filling of electrons $=$ low filling of holes $\Rightarrow$ Fermi surface becomes circular as the hole filling is small.



## - Electron on Honeycomb Lattice

Consider an electron hopping on a 2D honeycomb lattice (as in graphene).


Each unit cell contains two sites. Define the site coordinates

$$
\begin{equation*}
\boldsymbol{x}_{i}=\boldsymbol{x}_{\boldsymbol{n}, s}=n_{1} \boldsymbol{a}_{1}+n_{2} \boldsymbol{a}_{2}+\boldsymbol{r}_{s}, \tag{158}
\end{equation*}
$$

with $\boldsymbol{n}=\left(n_{1}, n_{2}\right) \in \mathbb{Z}^{2}, s=A, B$, and

$$
\left\{\begin{array}{l}
\boldsymbol{a}_{1}=(\sqrt{3}, 0)  \tag{159}\\
\boldsymbol{a}_{2}=\left(\frac{\sqrt{3}}{2}, \frac{3}{2}\right)
\end{array},\left\{\begin{array}{l}
\boldsymbol{r}_{A}=(\sqrt{3}, 1) \\
\boldsymbol{r}_{B}=\left(\frac{\sqrt{3}}{2}, \frac{1}{2}\right)
\end{array} .\right.\right.
$$

- The site index $i \leftrightarrow(\boldsymbol{n}, s)$ contains the unit cell and sublattice labels jointly.
- Introduce the nearest neighboring displacement vectors for later convenience

$$
\left\{\begin{array}{l}
\boldsymbol{\delta}_{1}=(0,-1)  \tag{160}\\
\boldsymbol{\delta}_{2}=\left(\frac{\sqrt{3}}{2}, \frac{1}{2}\right) . \\
\boldsymbol{\delta}_{3}=\left(-\frac{\sqrt{3}}{2}, \frac{1}{2}\right)
\end{array} .\right.
$$

Tight binding Hamiltonian (nearest neighbor hopping)

$$
\begin{equation*}
H=-t \sum_{\langle i j\rangle}(|i\rangle\langle j|+\text { h.c. }) . \tag{161}
\end{equation*}
$$

- The tight binding basis $|i\rangle$ is defined on each site, which may also be written as $|\boldsymbol{n}, s\rangle$ by the unit cell and sublattice labels.
- $\sum_{\langle i\rangle}$ sums over nearest neighboring links $\langle i j\rangle$ on the honeycomb lattice.

Introduce the quasi-momentum basis, for each sublattice separately $(s=A, B)$,

$$
\begin{align*}
& |\boldsymbol{k}, s\rangle=N^{-1 / 2} \sum_{n} e^{i k \cdot \boldsymbol{x}_{i}}|\boldsymbol{n}, s\rangle, \\
& |\boldsymbol{n}, s\rangle=N^{-1 / 2} \sum_{k} e^{-i \boldsymbol{k} \cdot \boldsymbol{x}_{i}}|\boldsymbol{k}, s\rangle . \tag{162}
\end{align*}
$$

- $N$ is the number of unit cells.
- The quasi-momentum is summed over the first Brillouin zone, which is a hexagon of side length $\frac{4 \pi}{3 \sqrt{3}}$.

- Recall that the first Brillouin zone is constructed as the Wigner-Seitz cell of the reciprocal lattice, spanned by the reciprocal basis

$$
\left\{\begin{array}{l}
\boldsymbol{b}_{1}=\left(\frac{2 \pi}{\sqrt{3}},-\frac{2 \pi}{3}\right)  \tag{163}\\
\boldsymbol{b}_{2}=\left(0, \frac{4 \pi}{3}\right)
\end{array}\right.
$$

- High symmetry points
$\Gamma:(0,0)+m_{1} \boldsymbol{b}_{1}+m_{2} \boldsymbol{b}_{2}$,

$$
\begin{aligned}
& K:\left(\frac{4 \pi}{3 \sqrt{3}}, 0\right)+m_{1} \boldsymbol{b}_{1}+m_{2} \boldsymbol{b}_{2}, \\
& K^{\prime}:\left(-\frac{4 \pi}{3 \sqrt{3}}, 0\right)+m_{1} \boldsymbol{b}_{1}+m_{2} \boldsymbol{b}_{2}, \\
& M:\left(0, \frac{2 \pi}{3}\right)+m_{1} \boldsymbol{b}_{1}+m_{2} \boldsymbol{b}_{2} .
\end{aligned}
$$

For a tight binding Hamiltonian that respects the lattice translation symmetry, the transformation to the quasi-momentum basis is given by

$$
\begin{align*}
& \sum_{i, j}|i\rangle H_{i j}\langle j|=\sum_{\boldsymbol{k}} \sum_{s, s^{\prime}} H_{\boldsymbol{k}, s s^{\prime}}|\boldsymbol{k}, s\rangle\left\langle\boldsymbol{k}, s^{\prime}\right|, \\
& H_{\boldsymbol{k}, s s^{\prime}}=\sum_{n} H_{i j} \boldsymbol{e}^{i \boldsymbol{k} \cdot\left(\boldsymbol{x}_{j}-\boldsymbol{x}_{i}\right)} \text { with } i=(\mathbf{0}, s), j=\left(\boldsymbol{n}, s^{\prime}\right) . \tag{165}
\end{align*}
$$

## Exc <br> 9 Derive Eq. (165).

Apply Eq. (165) to the tight binding Hamiltonian Eq. (161),

$$
\begin{align*}
& H=\sum_{k}\left(f_{k}|\boldsymbol{k}, B\rangle\langle\boldsymbol{k}, A|+f_{k}^{*}|\boldsymbol{k}, A\rangle\langle\boldsymbol{k}, B|\right),  \tag{171}\\
& f_{k}=-t\left(e^{i \boldsymbol{k} \cdot \delta_{1}}+e^{i \boldsymbol{k} \cdot \delta_{2}}+e^{i \boldsymbol{k} \cdot \delta_{3}}\right) .
\end{align*}
$$

- Represent in the $\{|k, A\rangle,|k, B\rangle\}$ basis, $H$ takes the matrix form

$$
H \bumpeq \bigoplus_{k} H_{k}, H_{k} \bumpeq\left(\begin{array}{cc}
0 & f_{k}^{*}  \tag{172}\\
f_{k} & 0
\end{array}\right),
$$

There are two bands (matching the number of sites in a unit cell). The band dispersions are given by the eigenvalues of $H_{k}$

$$
\begin{equation*}
\epsilon_{k, \pm}= \pm\left|f_{k}\right| . \tag{173}
\end{equation*}
$$




- Two bands touch at the Brillouin zone corners ( $K$ and $K^{\prime}$ points).

Expand the Hamiltonian around the band touching points (to the leading order in the small momentum deviation $\boldsymbol{\kappa}$ )

$$
\begin{align*}
& H_{K+\kappa} \bumpeq v_{F}\left(\begin{array}{cc}
0 & \kappa_{x}-i \kappa_{y} \\
\kappa_{x}+i \kappa_{y} & 0
\end{array}\right)+O\left(\kappa^{2}\right),  \tag{174}\\
& =v_{F}\left(\kappa_{x} \sigma^{1}+\kappa_{y} \sigma^{2}\right)+O\left(\kappa^{2}\right), \\
& H_{K^{\prime}+\kappa} \bumpeq v_{F}\left(\begin{array}{cc}
0 & -\kappa_{x}-i \kappa_{y} \\
-\kappa_{x}+i \kappa_{y} & 0
\end{array}\right)+O\left(\kappa^{2}\right),  \tag{175}\\
& =v_{F}\left(-\kappa_{x} \sigma^{1}+\kappa_{y} \sigma^{2}\right)+O\left(\kappa^{2}\right),
\end{align*}
$$

- These effective Hamiltonians describe 2D Dirac fermions of opposite chirality.
- When the chemical potential is set to the zero energy (at charge neutrality), the electronic system is in the Dirac semi-metal phase.
- Dirac cones (Dirac fermion dispersion). Near $K$ and $K^{\prime}$ points, the energy is linear in the momentum deviation $\boldsymbol{\kappa}$.

$$
\begin{equation*}
\epsilon_{K / K^{\prime}+\boldsymbol{\kappa}, \pm}= \pm v_{F}|\boldsymbol{\kappa}|, \tag{176}
\end{equation*}
$$

mimicking a relativistic particle with Fermi velocity

$$
\begin{equation*}
v_{F}=\frac{3 t}{2} \tag{177}
\end{equation*}
$$



- The points $K$ and $K^{\prime}$ are also called Dirac points, where the Dirac cones locate and the band gap close linearly. There are always even number of Dirac points in the Brillouin zone, known as the Fermion doubling.

Consider the nearest neighbor hopping tight binding model on a Kagome lattice (figure below).

HW

(i) How many bands do you expect?
(ii) Write down the single-particle Hamiltonian in the momentum space.
(iii) Diagonalize the Hamiltonian to calculate the band dispersions (you can use Mathematica), and show that there is an exact flat band.

## - Haldane Model

Adding next nearest neighbor hopping term $\lambda$ (Haldane hopping), with purely imaginary amplitude,

$$
\begin{equation*}
H=-t \sum_{\langle i j\rangle}(|i\rangle\langle j|+\text { h.c. })+\lambda \sum_{\langle i j\rangle\rangle}(i|i\rangle\langle j|+\text { h.c. }) . \tag{178}
\end{equation*}
$$

- Unlike real hopping, imaginary hopping is directional, as

$$
\begin{equation*}
(i|i\rangle\langle j|)^{\dagger}=-i|j\rangle\langle i| . \tag{179}
\end{equation*}
$$

Rule: the electron hopping from $j$ to $i$ (i.e. the $|i\rangle\langle j|$ term) has a hopping coefficient $+i$ if $j$ to $i$ is along the bond direction.

- The bond directions are assigned in the following pattern


Transform to the quasi-momentum basis specified in Eq. (162), the Hamiltonian reads

$$
\begin{aligned}
H & =\sum_{k}\left(f_{k}|\boldsymbol{k}, B\rangle\langle\boldsymbol{k}, A|+f_{k}^{*}|\boldsymbol{k}, A\rangle\langle\boldsymbol{k}, B|+g_{k}|\boldsymbol{k}, A\rangle\langle\boldsymbol{k}, A|-g_{k}|\boldsymbol{k}, B\rangle\langle\boldsymbol{k}, B|\right), \\
f_{k} & =-t\left(\boldsymbol{e}^{i \boldsymbol{k} \cdot \boldsymbol{\delta}_{1}}+\boldsymbol{e}^{i \boldsymbol{k} \cdot \boldsymbol{\delta}_{2}}+\boldsymbol{e}^{i \boldsymbol{k} \cdot \boldsymbol{\delta}_{3}}\right), \\
g_{k} & =-2 \lambda\left(\sin \boldsymbol{k} \cdot\left(\boldsymbol{\delta}_{1}-\boldsymbol{\delta}_{2}\right)+\sin \boldsymbol{k} \cdot\left(\boldsymbol{\delta}_{2}-\boldsymbol{\delta}_{3}\right)+\sin \boldsymbol{k} \cdot\left(\boldsymbol{\delta}_{3}-\boldsymbol{\delta}_{1}\right)\right) .
\end{aligned}
$$

- Represent in the $\{|k, A\rangle,|k, B\rangle\}$ basis, $H$ takes the matrix form

$$
H \simeq \bigoplus_{k} H_{k}, H_{k} \bumpeq\left(\begin{array}{cc}
g_{k} & f_{k}^{*}  \tag{181}\\
f_{k} & -g_{k}
\end{array}\right),
$$

- The band dispersions are modified to

$$
\begin{equation*}
\epsilon_{k, \pm}= \pm \sqrt{\left|f_{k}\right|^{2}+g_{k}^{2}} \tag{182}
\end{equation*}
$$



- The Haldane hopping term $\lambda$ opens a gap between the two bands, gapping out Dirac fermions at $K$ and $K^{\prime}$.

Expand the Hamiltonian around Dirac points $K$ and $K^{\prime}$

$$
\begin{align*}
& H_{K+\kappa}=\left(\begin{array}{cc}
m v_{F}^{2} & v_{F}\left(\kappa_{x}-i \kappa_{y}\right) \\
v_{F}\left(\kappa_{x}+i \kappa_{y}\right) & -m v_{F}^{2}
\end{array}\right)+O\left(\kappa^{2}\right),  \tag{183}\\
& =v_{F}\left(\kappa_{x} \sigma^{1}+\kappa_{y} \sigma^{2}\right)+m v_{F}^{2} \sigma^{3}+O\left(\kappa^{2}\right),
\end{align*}
$$

$$
\begin{align*}
& H_{K^{\prime}+\kappa}=\left(\begin{array}{cc}
-m v_{F}^{2} & v_{F}\left(-\kappa_{x}-i \kappa_{y}\right) \\
v_{F}\left(-\kappa_{x}+i \kappa_{y}\right) & m v_{F}^{2}
\end{array}\right)+O\left(\kappa^{2}\right),  \tag{184}\\
& =v_{F}\left(-\kappa_{x} \sigma^{1}+\kappa_{y} \sigma^{2}\right)-m v_{F}^{2} \sigma^{3}+O\left(\kappa^{2}\right),
\end{align*}
$$

with the Fermi velocity $v_{F}$ and the Dirac mass $m$ given by

$$
\begin{equation*}
v_{F}=\frac{3 t}{2}, m=\frac{3 \sqrt{3} \lambda}{v_{F}^{2}} . \tag{185}
\end{equation*}
$$

The dispersion relation is takes the form of a massive relativistic particle near Dirac points

$$
\begin{equation*}
\epsilon_{K / K^{\prime}+\kappa, \pm}= \pm \sqrt{v_{F}^{2} \boldsymbol{\kappa}^{2}+m^{2} v_{F}^{4}} . \tag{186}
\end{equation*}
$$



- When $\delta k$ is small, the energy expands to

$$
\begin{equation*}
\epsilon_{K / K^{\prime}+\kappa, \pm}= \pm\left(m v_{F}^{2}+\frac{\kappa^{2}}{2 m}+\ldots\right), \tag{187}
\end{equation*}
$$

which justifies the parameter $m$ as the mass of the Dirac fermion (also the effective mass of electron/hole near the band edge).

- Even if starting from non-relativistic electrons in graphene, relativistic behaviors can emerge at low-energy. This provides opportunities to simulate certain aspects of fundamental particle physics in condensed matter systems.


## - Chern Insulator and Integer Quantum Hall Effect

The band gap closes and reopens as $u$ goes across $\lambda=0$, signifying a phase transition between two insulators. Is there any difference between the $\lambda>0$ insulator and the $\lambda<0$ insulator?

Band structure does not tell the difference, need to look at wave functions (eigen states). Let $|\boldsymbol{k}, \pm\rangle$ be the eigen states of $H_{\boldsymbol{k}}$ with eigen energies $\epsilon_{k, \pm}$, i.e.

$$
\begin{equation*}
H_{k}|\boldsymbol{k}, \pm\rangle=\epsilon_{k, \pm}|\boldsymbol{k}, \pm\rangle \tag{188}
\end{equation*}
$$

- Berry connection of the vector bundle $|\boldsymbol{k}, \pm\rangle$, like a gauge potential in the momentum space,

$$
\begin{equation*}
\mathcal{A}_{k, \pm}=-i\langle\boldsymbol{k}, \pm| \nabla_{k}|\boldsymbol{k}, \pm\rangle . \tag{189}
\end{equation*}
$$

At each momentum point $\boldsymbol{k}$, the Berry connection has two components

$$
\begin{align*}
& \mathcal{A}_{k, \pm}^{x}=-i\langle\boldsymbol{k}, \pm| \partial_{k_{x}}|\boldsymbol{k}, \pm\rangle, \\
& \mathcal{A}_{\boldsymbol{k}, \pm}^{y}=-i\langle\boldsymbol{k}, \pm| \partial_{k_{y}}|\boldsymbol{k}, \pm\rangle . \tag{190}
\end{align*}
$$

- Berry curvature: curl of Berry connection (taking the $z$ component), like a magnetic field in the momentum space,

$$
\begin{equation*}
\mathcal{F}_{k, \pm}=\hat{z} \cdot\left(\nabla_{k} \times \mathcal{A}_{k, \pm}\right), \tag{191}
\end{equation*}
$$

or in term of components

$$
\begin{equation*}
\mathcal{F}_{k, \pm}=\partial_{k_{x}} \mathcal{A}_{k, \pm}^{y}-\partial_{k_{y}} \mathcal{A}_{k, \pm}^{x} . \tag{192}
\end{equation*}
$$

- For $2 \times 2$ Hamiltonian of the form $H_{\boldsymbol{k}} \bumpeq \boldsymbol{h}(\boldsymbol{k}) \cdot \boldsymbol{\sigma}$, the Berry curvature is given by

$$
\begin{equation*}
\mathcal{F}_{\boldsymbol{k}, \pm}= \pm \frac{1}{2|\boldsymbol{h}(\boldsymbol{k})|^{3}} \boldsymbol{h}(\boldsymbol{k}) \cdot\left(\partial_{k_{x}} \boldsymbol{h}(\boldsymbol{k}) \times \partial_{k_{y}} \boldsymbol{h}(\boldsymbol{k})\right) . \tag{193}
\end{equation*}
$$

Prove Eq. (193).

- Apply Eq. (193) to the Haldane model, one can show the distribution of Berry curvature in the Brillouin zone (for both upper and lower bands) as a function of $\lambda$

$$
\lambda / t=-0.1
$$

$$
\lambda / t=0.1
$$



- What is the physical effect of magnetic field in the momentum space? Recall: magnetic field $\boldsymbol{B}$ in the real space $\rightarrow$ electron will experience a Lorentz force
$\frac{d \boldsymbol{k}}{d t} \propto-\boldsymbol{v} \times \boldsymbol{B}=-\frac{d \boldsymbol{x}}{d t} \times \boldsymbol{B}$.
By analogy, switching from real space to momentum space effectively exchanges coordinate and momentum,
$\frac{d \boldsymbol{x}}{d t}=-\frac{d \boldsymbol{k}}{d t} \times \mathcal{F}$.
In the presence of an external electric field $\boldsymbol{E}$
$\frac{\hbar d \boldsymbol{k}}{d t}=-e \boldsymbol{E}$,
this will contribute to the current $\boldsymbol{J}$ by

$$
\begin{equation*}
\boldsymbol{J}=-e \frac{d \boldsymbol{x}}{d t}=\frac{e^{2}}{\hbar} \mathcal{F} \times \boldsymbol{E} . \tag{207}
\end{equation*}
$$

So $\left(e^{2} / \hbar\right) \mathscr{F}_{\boldsymbol{k}, \alpha}$ is the contribution to the Hall conductance from a single state $|\boldsymbol{k}, \alpha\rangle$.

- Chern number: integration of Berry curvature over the first Brillouin zone (in unit of $2 \pi$ ), like the total magnetic flux through the Brillouin zone,

$$
\begin{equation*}
C_{ \pm}=\frac{1}{2 \pi} \int_{\mathrm{BZ}} d^{2} \boldsymbol{k} \mathcal{F}_{k, \pm} . \tag{208}
\end{equation*}
$$

- The Chern number $C_{ \pm}$is separately define for each band (labeled by $\pm$). For two-band system, Chern numbers are opposite between upper and lower bands, $C_{+}=-C_{-}$.
- It turns out that $C_{ \pm} \in \mathbb{Z}$ is always an integer. For Haldane model,

$$
\begin{equation*}
C_{ \pm}= \pm \operatorname{sgn} \lambda . \tag{209}
\end{equation*}
$$

- As $\lambda$ is tuned across $\lambda=0$, the Chern number exchanges between the upper and lower bands.

- The Chern number is a topological number of the vector bundle $|\boldsymbol{k}, \pm\rangle$. The 2D insulators with non-trivial Chern numbers in occupied bands are called Chern insulators. The jump of Chern number at $\lambda=0$ signifies a topological transition between two distinct Chern insulators.
- The Hall conductance of the Chern insulator (at the low-temperature limit) equals the total the Chern numbers $C_{\alpha}$ of all occupied bands (bands below the Fermi level) times the quantum conductance $e^{2} / h$.

$$
\begin{equation*}
\sigma_{H}=\frac{e^{2}}{h} \sum_{\alpha \in \mathrm{occ} .} \mathcal{C}_{\alpha} . \tag{210}
\end{equation*}
$$

Argument: the Hall conductance of a band averages the contribution from all states in the band

$$
\begin{equation*}
\sigma_{H}=\frac{e^{2}}{\hbar} \int \frac{d^{2} \boldsymbol{k}}{(2 \pi)^{2}} \mathcal{F}_{\boldsymbol{k}, \alpha}=\frac{e^{2}}{h} \frac{1}{2 \pi} \int d^{2} \boldsymbol{k} \mathcal{F}_{\boldsymbol{k}, \alpha}=\frac{e^{2}}{h} \mathcal{C}_{\alpha} . \tag{211}
\end{equation*}
$$

- The phenomenon that the Hall conductance quantize to integer multiplies of $e^{2} / h$ is called the integer quantum Hall effect.

Near the phase transition, the Berry curvature concentrated at the Dirac points. Around each Dirac point, the effective Hamiltonian reads (setting $v_{F}=1$ for simplicity)

$$
\begin{align*}
& H_{K+\kappa} \bumpeq \kappa_{x} \sigma^{1}+\kappa_{y} \sigma^{2}+m \sigma^{3}, \\
& H_{K^{\prime}+\kappa} \bumpeq-\kappa_{x} \sigma^{1}+\kappa_{y} \sigma^{2}-m \sigma^{3}, \tag{212}
\end{align*}
$$

- Using Eq. (193), the Berry curvature can be evaluated

$$
\begin{equation*}
\mathcal{F}_{K+\boldsymbol{\kappa}, \pm}=\mathcal{F}_{K^{\prime}+\boldsymbol{\kappa}, \pm}= \pm \frac{m}{2\left(\boldsymbol{\kappa}^{2}+m^{2}\right)^{3 / 2}} \tag{213}
\end{equation*}
$$

- Each massive Dirac fermion contribute $\pm 1 / 2$ to the band Chern number. For example, around $K$ point

$$
\begin{equation*}
\mathcal{C}_{K, \pm}=\frac{1}{2 \pi} \int d^{2} \boldsymbol{\kappa} \mathcal{F}_{K+\kappa, \pm}= \pm \frac{1}{2} \frac{m}{|m|}= \pm \frac{1}{2} \operatorname{sgn} m . \tag{214}
\end{equation*}
$$

Same result will be obtained around $K^{\prime}, C_{K, \pm}=C_{K^{\prime}, \pm}= \pm \frac{1}{2} \operatorname{sgn} m$, such that the Chern number follows

$$
\begin{equation*}
C_{ \pm}=C_{K, \pm}+C_{K^{\prime}, \pm}= \pm \operatorname{sgn} m, \tag{215}
\end{equation*}
$$

confirming the observation in Eq. (209).

## - Classifying Topological Insulators in 2D

Two band insulators can belong to the same or different topological phases, depending on whether or not there exist a smooth deformation of the Hamiltonian that connects the two insulators without closing the gap.

Assuming translation symmetry, any 2D band insulator can be described by an effective Hamiltonian that focus on the upper and lower bands across the Fermi level

$$
\begin{equation*}
H \bumpeq \bigoplus_{k} H_{k}, H_{k} \bumpeq \boldsymbol{h}(\boldsymbol{k}) \cdot \boldsymbol{\sigma} . \tag{216}
\end{equation*}
$$

- The band gap is set by $|\boldsymbol{h}(\boldsymbol{k})|$. To keep the gap open, must have

$$
\begin{equation*}
\forall \boldsymbol{k}:|\boldsymbol{h}(\boldsymbol{k})|>0, \tag{217}
\end{equation*}
$$

meaning that $\boldsymbol{h}(\boldsymbol{k}) \in \mathbb{R}^{3} \backslash\{\mathbf{0}\}$. For 2 D system, $\boldsymbol{k} \in T^{2}$ (2D torus).

- All smooth deformations of the function $\boldsymbol{h}: T^{2} \rightarrow \mathbb{R}^{3} \backslash\{\mathbf{0}\}$ are classified by the homotopy group

$$
\begin{equation*}
\pi_{2}\left(\mathbb{R}^{3} \backslash\{\mathbf{0}\}\right) \cong \pi_{2}\left(S^{2}\right) \cong \mathbb{Z} \tag{218}
\end{equation*}
$$

which is the integer addition group. Each class is labeled by an integer topological index $\omega$, which corresponds to the winding number of $\boldsymbol{h}$ in the 2D Brillouin zone

$$
\begin{equation*}
\omega=\frac{1}{4 \pi} \int_{\mathrm{BZ}} d^{2} \boldsymbol{k} \frac{1}{|\boldsymbol{h}(\boldsymbol{k})|^{3}} \boldsymbol{h}(\boldsymbol{k}) \cdot\left(\partial_{k_{x}} \boldsymbol{h}(\boldsymbol{k}) \times \partial_{k_{y}} \boldsymbol{h}(\boldsymbol{k})\right) . \tag{219}
\end{equation*}
$$

- By Eq. (193), the winding number is the same as the Chern number. Thus topological insulators (with no additional symmetry other than $\mathrm{U}(1)$ ) is classified by the band Chern number.

Both $\lambda>0$ and $\lambda<0$ insulators are non-trivial topological insulators with Chern number $\mp 1$ in the lower band. The trivial insulator in this system can be achieved by adding a staggered onsite potential $\delta$

$$
\begin{equation*}
H=-t \sum_{\langle i j\rangle}(|i\rangle\langle j|+\text { h.c. })+\lambda \sum_{\langle\langle i\rangle\rangle}(i|i\rangle\langle j|+\text { h.c. })+\delta \sum_{i}(-)^{i}|i\rangle\langle i|, \tag{220}
\end{equation*}
$$

where $(-)^{i}=+1$ if $i \in A$ and $(-)^{i}=-1$ if $i \in B$.

- In the momentum space, the Hamiltonian still takes the form of

$$
H \simeq \bigoplus_{k} H_{k}, H_{k} \simeq\left(\begin{array}{cc}
g_{k} & f_{k}^{*}  \tag{221}\\
f_{k} & -g_{k}
\end{array}\right),
$$

but the function $g_{k}$ is updated to

$$
\begin{equation*}
g_{\boldsymbol{k}}=\delta-2 \lambda\left(\sin k \cdot\left(\boldsymbol{\delta}_{1}-\boldsymbol{\delta}_{2}\right)+\sin \boldsymbol{k} \cdot\left(\boldsymbol{\delta}_{2}-\boldsymbol{\delta}_{3}\right)+\sin \boldsymbol{k} \cdot\left(\boldsymbol{\delta}_{3}-\boldsymbol{\delta}_{1}\right)\right) . \tag{222}
\end{equation*}
$$

- Expanding around $K$ and $K^{\prime}$,

$$
\begin{align*}
& H_{K+\kappa} \bumpeq v_{F}\left(\kappa_{x} \sigma^{1}+\kappa_{y} \sigma^{2}\right)+m_{K} v_{F}^{2} \sigma^{3}+O\left(\kappa^{2}\right),  \tag{223}\\
& H_{K^{\prime}+\kappa} \simeq v_{F}\left(-\kappa_{x} \sigma^{1}+\kappa_{y} \sigma^{2}\right)-m_{K^{\prime}} v_{F}^{2} \sigma^{3}+O\left(\kappa^{2}\right),
\end{align*}
$$

the Dirac masses are different

$$
\begin{align*}
& m_{K}=\frac{1}{v_{F}^{2}}(3 \sqrt{3} \lambda+\delta),  \tag{224}\\
& m_{K^{\prime}}=\frac{1}{v_{F}^{2}}(3 \sqrt{3} \lambda-\delta) .
\end{align*}
$$

- The band Chern numbers

$$
\begin{equation*}
C_{ \pm}=C_{K, \pm}+C_{K^{\prime}, \pm}= \pm \frac{1}{2}\left(\operatorname{sgn} m_{K}+\operatorname{sgn} m_{K^{\prime}}\right) . \tag{225}
\end{equation*}
$$

If $\lambda=0$ and $\delta \neq 0$, the masses are opposite between $K$ and $K^{\prime}$ valleys $\Rightarrow$ the Chern number from both valleys cancels, i.e. $C_{ \pm}=0 \Rightarrow$ the insulator is in the trivial phase.

## - Chiral Edge Mode

A prominent feature of the Chern insulators lies in the robust chiral edge modes. Consider placing the Haldane model on a honeycomb lattice with

- periodic boundary condition along $x$-direction (preserving translation symmetry along $x$-direction, $k_{x}$ is still well-defined),
- open boundary condition along $y$-direction (top and bottom edges breaks translation symmetry along $y$-direction, can not define $k_{y}$ ),


Use mixed basis (transform to the momentum space only in the $x$-direction)

$$
\begin{equation*}
\left|k_{x}, y_{i}, s\right\rangle=\sum_{x_{i}} e^{-i k_{x} x_{i}}|i\rangle \tag{226}
\end{equation*}
$$

- The Hamiltonian is diagonal in $k_{x}$ (because $k_{x}$ is a good quantum number)

$$
\begin{equation*}
H=\sum_{k_{x}}\left|k_{x}\right\rangle H\left(k_{x}\right)\left\langle k_{x}\right|, \tag{227}
\end{equation*}
$$

where

$$
\begin{align*}
& H\left(k_{x}\right)=H_{t}\left(k_{x}\right)+H_{\lambda}\left(k_{x}\right)+H_{\delta}\left(k_{x}\right) \\
& H_{t}\left(k_{x}\right)=-t \sum_{y}\left(|y, B\rangle\langle y, A|+2 \cos \frac{\sqrt{3} k_{x}}{2}\left|y+a_{y}, A\right\rangle\langle y, B|+\text { h.c. }\right) \\
& H_{\lambda}\left(k_{x}\right)=-2 \lambda \sum_{k_{x}, y}\left(\sin \sqrt{3} k_{x}(|y, A\rangle\langle y, A|-|y, B\rangle\langle y, B|)-\right.  \tag{228}\\
& \left.\quad \sin \frac{\sqrt{3} k_{x}}{2}\left(\left|y+a_{y}, A\right\rangle\langle y, A|-\left|y+a_{y}, B\right\rangle\langle y, B|+\text { h.c. }\right)\right) \\
& H_{\delta}=\delta \sum_{k_{x}, y}(|y, A\rangle\langle y, A|-|y, B\rangle\langle y, B|),
\end{align*}
$$

with $a_{y}=3 / 2$ being the inter-layer spacing.

- Further diagonalize $H\left(k_{x}\right)$ for every $k_{x}$

$$
\begin{equation*}
H\left(k_{x}\right)\left|u_{n}\left(k_{x}\right)\right\rangle=\epsilon_{n}\left(k_{x}\right)\left|u_{n}\left(k_{x}\right)\right\rangle \tag{229}
\end{equation*}
$$

Bulk modes (in black) and edge modes (in red)


- Edge mode wave function ( $y$-dependence). Edge modes are confined on the boundary. The wave functions decay exponentially into the bulk.

$$
k_{x}=0.0
$$




- Color every point $\left(k_{x}, \boldsymbol{\epsilon}_{n}\left(k_{x}\right)\right)$ by the weight of the corresponding mode $\left|u_{n}\left(k_{x}\right)\right\rangle$ on a given site. Define the spectral function $A_{y, s}$ on layer $y$ sublattice $s$,

$$
\begin{equation*}
A_{y, s}\left(k_{x}, \epsilon\right)=\sum_{n}\left|\left\langle y, s \mid u_{n}\left(k_{x}\right)\right\rangle\right|^{2} \delta\left(\epsilon-\epsilon_{n}\left(k_{x}\right)\right) . \tag{230}
\end{equation*}
$$

- Bottom boundary $(y=1, s=A)$

- Effective dispersion of boundary modes: $\epsilon\left(k_{x}\right) \simeq-v k_{x} \Rightarrow$ Left-moving modes.
- Edge modes merge into bulk modes as the dispersion touches the bulk band.
- Top boundary $\left(y=L_{y}, s=B\right)$

- Effective dispersion of boundary modes: $\epsilon\left(k_{x}\right) \simeq+v k_{x} \Rightarrow$ Right-moving modes.
- Edge modes merge into bulk modes as the dispersion touches the bulk band.
- Chiral edge mode: The edge mode circulates around the material in a chiral manner.

- Quantized Hall conductance. An electric field $E_{y}$ creates electrostatic potential difference $V_{y}$ between top and bottom boundaries $\Rightarrow$ difference in electron chemical potentials $\mu_{\text {top }}$ and $\mu_{\mathrm{btm}}$

$$
\begin{equation*}
-e E_{y} L_{y}=-e V_{y}=\mu_{\mathrm{top}}-\mu_{\mathrm{btm}}, \tag{231}
\end{equation*}
$$


more electrons occupy the top edge modes compared to bottom edge modes

$$
\begin{equation*}
N_{\mathrm{top}}-N_{\mathrm{btm}}=\frac{k_{x, \mathrm{top}}-k_{x, \mathrm{btm}}}{\left(2 \pi / L_{x}\right)}=\frac{\mu_{\mathrm{top}}-\mu_{\mathrm{btm}}}{v \hbar\left(2 \pi / L_{x}\right)}=\frac{-e E_{y} L_{x} L_{y}}{v h}, \tag{232}
\end{equation*}
$$

more right-moving electrons than left-moving electrons contributes to a net current

$$
\begin{equation*}
I_{x}=j_{x} L_{y}=-e v \frac{N_{\mathrm{top}}-N_{\mathrm{btm}}}{L_{x}}=\frac{e^{2} E_{y} L_{y}}{h} . \tag{233}
\end{equation*}
$$

Hall conductance $\sigma_{H}$ is defined by

$$
\begin{equation*}
j_{x}=\sigma_{H} E_{y}, \tag{234}
\end{equation*}
$$

Eq. (233) implies

$$
\begin{equation*}
\sigma_{H}=\frac{e^{2}}{h} \tag{235}
\end{equation*}
$$

which is indeed quantized (integer) in unit of the quantum conductance $e^{2} / h$.

- Bulk-boundary correspondence. The number of chiral edge modes (boundary property) $\Leftrightarrow$ the quantized Hall conductance / the band Chern number (bulk property).


## - General Theory of Electrons in Crystals

## - Nearly Free Electron Model

The tight binding models provides a real-space perspective to understand electrons in a crystal. An alternative approach is the nearly free electron model, which provides a momentum-space perspective to the same problem.

Start with free electron in the empty space, the Hamiltonian is diagonal in momentum eigen basis

$$
\begin{equation*}
H_{0}=\sum_{k}|\boldsymbol{k}\rangle \frac{\hbar^{2} \boldsymbol{k}^{2}}{2 m}\langle\boldsymbol{k}| . \tag{236}
\end{equation*}
$$

- $|\boldsymbol{k}\rangle$ : plane wave state of electron $\psi_{k}(\boldsymbol{x}) \sim \boldsymbol{e}^{i \boldsymbol{k} \boldsymbol{x}}$, labeled by the wave vector $\boldsymbol{k}$.

$$
\begin{equation*}
|k\rangle=\int d x \psi_{k}(x)|x\rangle=\frac{1}{V^{1 / 2}} \int d x e^{i k \cdot x}|x\rangle . \tag{237}
\end{equation*}
$$

- $V$ - volume of the system, to provide appropriate normalization for the wave function.

When the electron is moving in a crystal, it also experience the potential energy from the lattice background

$$
\begin{equation*}
H=H_{0}+\int d x|x\rangle V(x)\langle x| . \tag{238}
\end{equation*}
$$

- A key feature is that $V(\boldsymbol{x})$ is periodic

$$
\begin{equation*}
V(\boldsymbol{x})=V(\boldsymbol{x}+\boldsymbol{R}), \tag{239}
\end{equation*}
$$

where $\boldsymbol{R}$ is any lattice vector. Because atoms are arranged on a periodic lattice in the crystal.

- Transform the potential energy to the momentum space

$$
\begin{equation*}
\int d x|x\rangle V(x)\langle x|=\sum_{k, k^{\prime}}\left|\boldsymbol{k}^{\prime}\right\rangle V_{k^{\prime}-k}\langle\boldsymbol{k}|, \tag{240}
\end{equation*}
$$

with $V_{q}$ being the Fourier transform of $V(x)$

$$
\begin{equation*}
V_{q}=\frac{1}{V} \int d x V(x) e^{-i q x} \tag{241}
\end{equation*}
$$

## Exc 11 Derive Eq. (240).

- However, the periodicity of $V(\boldsymbol{x})$ in Eq. (239) puts a strong constraint on its Fourier transform $V_{q}$ in Eq. (241) that

$$
\begin{equation*}
V_{q}=e^{-i q \cdot R} V_{q} \tag{243}
\end{equation*}
$$

for any lattice vector $\boldsymbol{R}$. For this equation to hold,

- Either $\boldsymbol{q}$ satisfies the condition $\forall \boldsymbol{R}: \boldsymbol{e}^{-i \boldsymbol{q} \cdot \boldsymbol{R}}=1$, i.e. $\boldsymbol{q}=\boldsymbol{G} \in$ reciprocal lattice.
- Or $\boldsymbol{q}$ is not on the reciprocal lattice, then $V_{\boldsymbol{q}}=0$ must vanish.

This means

$$
\begin{equation*}
V_{q}=\sum_{G} V_{G} \delta(\boldsymbol{q}-\boldsymbol{G}) \tag{244}
\end{equation*}
$$

Then the full Hamiltonian reads

$$
\begin{equation*}
H=\sum_{k}\left(|\boldsymbol{k}\rangle \frac{\hbar^{2} \boldsymbol{k}^{2}}{2 m}\langle\boldsymbol{k}|+\sum_{\boldsymbol{G}}|\boldsymbol{k}+\boldsymbol{G}\rangle V_{\boldsymbol{G}}\langle\boldsymbol{k}|\right) . \tag{245}
\end{equation*}
$$

with

- $G$ is summed over all reciprocal vectors on the reciprocal lattice,
- $V_{G}$ describes the scattering strength that an electron is scattered from momentum $\hbar \boldsymbol{k}$ to $\hbar(\boldsymbol{k}+\boldsymbol{G})$ on the lattice, and is given by

$$
\begin{equation*}
V_{G}=\frac{1}{V} \int d \boldsymbol{x} V(\boldsymbol{x}) e^{-i \boldsymbol{G} \cdot \boldsymbol{x}} \tag{246}
\end{equation*}
$$

- The $|\boldsymbol{k}\rangle$ state can only be mixed with $|\boldsymbol{k}+\boldsymbol{G}\rangle$ states related by the lattice momentum. This is a manifestation of the Laue condition (the conservation of quasi-momentum).


## - Electron in 1D Periodic Potential

Consider a 1D periodic potential

$$
\begin{equation*}
V(x)=V_{0}+2 V_{1} \cos (2 \pi x)+2 V_{2} \cos (4 \pi x) . \tag{247}
\end{equation*}
$$



- Lattice constant $a=1 \Rightarrow$ Reciprocal lattice constant $b=2 \pi / a=2 \pi \Rightarrow$ Reciprocal lattice vectors $G_{m}=m b=2 \pi m(m \in \mathbb{Z}$ - the Miller index, not the electron mass)
- Scattering strength

$$
V_{G}= \begin{cases}V_{0} & G=0  \tag{248}\\ V_{1} & G= \pm 2 \pi \\ V_{2} & G= \pm 4 \pi \\ 0 & \text { otherwise }\end{cases}
$$

- Takes the set of basis states given a momentum $k \in \mathrm{BZ}$ in the first Brillouin zone

$$
\begin{equation*}
\ldots,|k-4 \pi\rangle,|k-2 \pi\rangle,|k\rangle,|k+2 \pi\rangle,|k+4 \pi\rangle, \ldots \tag{249}
\end{equation*}
$$

the Hamiltonian can be represented as a matrix

$$
H_{k}=\left(\begin{array}{ccccccc}
\ddots & \ddots & \ddots & & & &  \tag{250}\\
\ddots & \xi_{k-4 \pi} & V_{1} & V_{2} & & & \\
\ddots & V_{1} & \xi_{k-2 \pi} & V_{1} & V_{2} & & \\
& V_{2} & V_{1} & \xi_{k} & V_{1} & V_{2} & \\
& & V_{2} & V_{1} & \xi_{k+2 \pi} & V_{1} & \ddots \\
& & & V_{2} & V_{1} & \xi_{k+4 \pi} & \ddots \\
& & & & \ddots & \ddots & \ddots
\end{array}\right),
$$

where the diagonal energy is given by

$$
\begin{equation*}
\xi_{k}=\frac{\hbar^{2} k^{2}}{2 m}+V_{0} . \tag{251}
\end{equation*}
$$

- Diagonalize the Hamiltonian to fine the eigen energies and eigenstates

$$
\begin{equation*}
H_{k}|\alpha, k\rangle=\epsilon_{\alpha, k}|\alpha, k\rangle \tag{252}
\end{equation*}
$$

- $\alpha$ - band index, labels the $n$th eigen state of $H_{k}$ at each $k$
- $k$ - quasi-momentum, there is no need to take $k$ out side the first Brillouin zone as that do not leads to a new set of basis states.
- $\epsilon_{\alpha, k}$ - dispersion relation of the $\alpha$ th energy band (corresponds to the $n$th eigenvalue of $H_{k}$ )


Extended




- Band gap opens at the Brillouin zone boundary.
- The dispersion can be unfolded to extended Brillouin zones following

$$
\epsilon_{\alpha, k} \rightarrow \epsilon\left(k-2 \pi(-)^{\alpha}\left\lfloor\frac{\alpha}{2}\right\rfloor \operatorname{sgn}(k)\right) .
$$

- $|\alpha, k\rangle$ - eigenstate, as a linear combination of basis states

$$
\begin{equation*}
|\alpha, k\rangle=\sum_{m \in \mathbb{Z}} \tilde{u}_{\alpha, k, 2 \pi m}|k+2 \pi m\rangle, \tag{253}
\end{equation*}
$$

in real space basis

$$
\begin{equation*}
\psi_{\alpha, k}(x)=\langle x \mid \alpha, k\rangle=\sum_{m \in \mathbb{Z}} \tilde{u}_{\alpha, k, 2 \pi m} \boldsymbol{e}^{i(k+2 \pi m) x} \tag{254}
\end{equation*}
$$



- Every eigenstate is a plane wave $\boldsymbol{e}^{i k x}$ modulated by a periodic function $u_{\alpha, k}(x)$ (in response to the periodic potential). $u_{\alpha, k}(x)$ is called the Bloch function, defined as

$$
\begin{equation*}
u_{\alpha, k}(x)=\sum_{m \in \mathbb{Z}} \tilde{u}_{\alpha, k, 2 \pi m} \boldsymbol{e}^{i 2 \pi m x} \tag{255}
\end{equation*}
$$

such that Eq. (254) explicitly takes the form of

$$
\begin{equation*}
\psi_{\alpha, k}(x)=u_{\alpha, k}(x) \boldsymbol{e}^{i k x} . \tag{256}
\end{equation*}
$$



- The Bloch function is periodic in $x$. Because if $x$ is shifted by a lattice vector $x \rightarrow x+n$ ( $n \in \mathbb{Z}$ ), by definition, we have

$$
\begin{align*}
& u_{\alpha, k}(x+n)=\sum_{m \in \mathbb{Z}} \tilde{u}_{\alpha, k, 2 \pi m} e^{i 2 \pi m x} e^{i 2 \pi m n} \\
& =\sum_{m \in \mathbb{Z}} \tilde{u}_{\alpha, k, 2 \pi m} e^{i 2 \pi m x}=u_{\alpha, k}(x) \tag{257}
\end{align*}
$$

In the near free electron model, calculate the effective mass of electron at the boundary between the $m$ th and $(m+1)$ th Brillouin zone (where the band gap opens). [Hint: focus on the $|k= \pm m \pi\rangle$ states and apply the 2 nd order perturbation theory].

## - Bloch Theorem

Bloch theorem: An electron in a periodic potential $V(\boldsymbol{x})=V(\boldsymbol{x}+\boldsymbol{R})$ has eigenstates of the form

$$
\begin{equation*}
\psi_{\alpha, k}(x)=\langle\boldsymbol{x} \mid \alpha, \boldsymbol{k}\rangle=u_{\alpha, k}(\boldsymbol{x}) e^{i k \cdot x}, \tag{258}
\end{equation*}
$$

where the Bloch function $u_{\alpha, k}(\boldsymbol{x})=u_{\alpha, k}(\boldsymbol{x}+\boldsymbol{R})$ is periodic in $\boldsymbol{x}$ (with the same periodicity as the potential), and the quasi-momentum $\boldsymbol{k}$ is chosen within the first Brillouin zone.

- Proof: in the Hamiltonian Eq. (245), because the scattering term $\sum_{\boldsymbol{G}}|\boldsymbol{k}+\boldsymbol{G}\rangle V_{\boldsymbol{G}}\langle\boldsymbol{k}|$ only connects momentum eigenstates $|\boldsymbol{k}\rangle$ and $|\boldsymbol{k}+\boldsymbol{G}\rangle$ that are related by the reciprocal lattice vector $\boldsymbol{G}$. So the energy eigenstates (eigenstates of $H$ ) must be a linear combination of these momentum eigenstates, with some combination coefficients $\tilde{u}_{\alpha, \boldsymbol{k}, \boldsymbol{G}}$

$$
\begin{equation*}
|\alpha, \boldsymbol{k}\rangle=\sum_{G} \tilde{u}_{\alpha, \boldsymbol{k}, \boldsymbol{G}}|\boldsymbol{k}+\boldsymbol{G}\rangle, \tag{259}
\end{equation*}
$$

where $\alpha$ is the band index (labeling the $\alpha$ th eigenstate of $H$ ). In real space basis,

$$
\begin{align*}
& \langle\boldsymbol{x} \mid \alpha, \boldsymbol{k}\rangle=\sum_{G} \tilde{u}_{\alpha, \boldsymbol{k}, \boldsymbol{G}}\langle\boldsymbol{x} \mid \boldsymbol{k}+\boldsymbol{G}\rangle \\
& =\sum_{G} \tilde{u}_{\alpha, k, G} e^{i(k+G) \cdot x}  \tag{260}\\
& =u_{\alpha, k}(\boldsymbol{x}) e^{i k x},
\end{align*}
$$

where the Bloch function $u_{\alpha, k}(\boldsymbol{x})$ is introduced as the Fourier transform of the coefficients $\tilde{u}_{\alpha, k, G}$,

$$
\begin{equation*}
u_{\alpha, k}(x)=\sum_{G} \tilde{u}_{\alpha, G} e^{i G \cdot x}, \tag{261}
\end{equation*}
$$

which must be periodic in $\boldsymbol{x}$, as

$$
\begin{equation*}
u_{\alpha, k}(x+\boldsymbol{R})=\sum_{G} \tilde{u}_{\alpha, G} e^{i G \cdot x} e^{i G \cdot R}=u_{\alpha, k}(x), \tag{262}
\end{equation*}
$$

given that $\boldsymbol{e}^{i \boldsymbol{G} \cdot \boldsymbol{R}}=1$ by definition of the reciprocal lattice.

- $\boldsymbol{k}$ is called the quasi-momentum because $|\alpha, \boldsymbol{k}\rangle$ state is a superposition of different momentum eigenstates, that does not has a definite momentum, but it labels a equivalent class of momenta that are all related by the Laue condition.

- The electron still propagate in the form of a (modulated) plane wave in the crystal, with a quasi-momentum, similar to the plane wave state of a free electron.
Even though the potential that the electron feels from each atom is extremely strong, the electrons will still behave almost as if they do not see the atoms at all!

When I started to think about it, I felt that the main problem was to explain how the electrons could sneak by all the ions in a metal so as to avoid a mean free path of the order of atomic distance ... By straight Fourier analysis I found to my delight that the wave differed from the plane wave of
free electrons only by a periodic modulation.

- Felix Bloch (1952 Nobel Prize)


## - Equation of Motion for Bloch Electron

A free electron in an electric field

- Classical mechanics (Newton's 2nd law)

$$
\begin{equation*}
\frac{d \boldsymbol{p}}{d t}=\boldsymbol{F}=-e \boldsymbol{E} . \tag{264}
\end{equation*}
$$

- Quantum mechanics (Schrödinger equation)

$$
\begin{equation*}
i \hbar \partial_{t} \psi=H \psi, \tag{265}
\end{equation*}
$$

formal solution:

$$
\begin{equation*}
\psi \rightarrow \boldsymbol{e}^{-\frac{i}{\hbar} H t} \psi, \tag{266}
\end{equation*}
$$

the electron matter wave will accumulate the phase in time in the rate that is set by the energy.
The potential energy of an electron in the electric field is

$$
\begin{equation*}
V(\boldsymbol{x})=e \boldsymbol{E} \cdot \boldsymbol{x} \tag{267}
\end{equation*}
$$

A plane wave state $|\boldsymbol{k}\rangle$ will evolve in the electric field as

$$
\begin{equation*}
e^{i k x} \rightarrow \boldsymbol{e}^{-\frac{i}{\hbar} V(x) t} e^{i k x}=e^{i\left(k-\frac{1}{\hbar} e E t\right) \cdot x}, \tag{268}
\end{equation*}
$$

meaning that the momentum $\hbar \boldsymbol{k}$ of the electron will change in time as

$$
\begin{equation*}
\hbar \boldsymbol{k} \rightarrow \hbar \boldsymbol{k}-e \boldsymbol{E} t, \tag{269}
\end{equation*}
$$

or described by

$$
\begin{equation*}
\frac{d(\hbar \boldsymbol{k})}{d t}=-e \boldsymbol{E} \tag{270}
\end{equation*}
$$

matching the classical mechanics result.
For a Bloch electron (electron in a crystal)

$$
\begin{equation*}
|\alpha, \boldsymbol{k}\rangle=\sum_{G} \tilde{u}_{\alpha, k, G}|\boldsymbol{k}+\boldsymbol{G}\rangle, \tag{271}
\end{equation*}
$$

in the presence of the electric field $\boldsymbol{E}$, every (actual) momentum eigenstate $|\boldsymbol{k}\rangle$ will evolve in time as

$$
\begin{equation*}
|\boldsymbol{k}\rangle \rightarrow|\boldsymbol{k}-(e / \hbar) \boldsymbol{E} t\rangle . \tag{272}
\end{equation*}
$$

Therefore the Bloch state evolves as (assuming (e/ $\hbar) E t \ll 2 \pi$, such that $\tilde{u}_{\alpha, k, G}$ remains approximately the same)

$$
|\alpha, \boldsymbol{k}\rangle \rightarrow \sum_{G} \tilde{u}_{\alpha, k, \boldsymbol{G}}|\boldsymbol{k}-(e / \hbar) \boldsymbol{E} t+\boldsymbol{G}\rangle
$$

$$
\begin{aligned}
& \simeq \sum_{\boldsymbol{G}} \tilde{u}_{\alpha, \boldsymbol{k}-(e / \hbar) \boldsymbol{E} t, \boldsymbol{G}}|\boldsymbol{k}-(e / \hbar) \boldsymbol{E} t+\boldsymbol{G}\rangle \\
& =|\alpha, \boldsymbol{k}-(e / \hbar) \boldsymbol{E} t\rangle,
\end{aligned}
$$

meaning that the quasi-momentum also satisfies Newton's 2nd law

$$
\begin{equation*}
\frac{d(\hbar \boldsymbol{k})}{d t}=-e \boldsymbol{E}=\boldsymbol{F} \tag{274}
\end{equation*}
$$

## Metal (Fermi Gas) Phase

## - Thermodynamic Properties

## - Fermi-Dirac Distribution

Electron is a fermion. Its finite-temperature behavior is determined by the Fermi-Dirac distribution.

- Pauli exclusion principle. A fermion mode can either be empty or occupied by one fermion, but not occupied by multiple fermions.

Consider a system containing only one fermion mode. Let $n$ be the occupation number of the fermion mode

$$
n=\left\{\begin{array}{ll}
0 & \text { empty }  \tag{275}\\
1 & \text { occupied }
\end{array} .\right.
$$

- Total energy of the system

$$
E=\epsilon n=\left\{\begin{array}{ll}
0 & \text { empty }  \tag{276}\\
\epsilon & \text { occupied }
\end{array} .\right.
$$

- Total fermion number of the system

$$
N=n=\left\{\begin{array}{ll}
0 & \text { empty }  \tag{277}\\
1 & \text { occupied }
\end{array} .\right.
$$

- Probability to observe the system in the state with occupation number $n$ is

$$
\begin{equation*}
p_{n}=\frac{1}{Z} e^{-\beta(E-\mu N)}=\frac{1}{Z} e^{-\beta(\epsilon-\mu) n}, \tag{278}
\end{equation*}
$$

where $Z$ is the partition function (quantum, grand canonical ensemble)

$$
\begin{equation*}
Z=\sum_{n=0,1} e^{-\beta(\epsilon-\mu) n}=1+e^{-\beta(\epsilon-\mu)} . \tag{279}
\end{equation*}
$$

- $\beta=1 /\left(k_{B} T\right): k_{B}$ - Boltzmann constant, $T$ - temperature.
- $\mu$-chemical potential.

More explicitly

$$
\begin{equation*}
p_{0}=\frac{1}{1+\boldsymbol{e}^{-\beta(\epsilon-\mu)}}, p_{1}=\frac{1}{\boldsymbol{e}^{\beta(\epsilon-\mu)}+1} . \tag{280}
\end{equation*}
$$



- Average occupation number

$$
\begin{equation*}
\langle n\rangle=\sum_{n=0,1} n p_{n}=p_{1}=n_{\mathrm{F}}(\beta(\epsilon-\mu)), \tag{281}
\end{equation*}
$$

where $n_{\mathrm{F}}$ is the Fermi-Dirac distribution function

$$
\begin{equation*}
n_{\mathrm{F}}(\beta(\epsilon-\mu))=\frac{1}{e^{\beta(\epsilon-\mu)}+1} . \tag{282}
\end{equation*}
$$

describing the average number of fermions occupying the mode of energy $\epsilon$.

- Average energy

$$
\begin{align*}
& \langle E\rangle=\sum_{n=0,1} E p_{n}  \tag{283}\\
& =\epsilon n_{\mathrm{F}}(\beta(\epsilon-\mu)) .
\end{align*}
$$

- Average fermion (electron) number

$$
\begin{gather*}
\langle N\rangle=\sum_{n=0,1} N p_{n}  \tag{284}\\
=n_{\mathrm{F}}(\beta(\epsilon-\mu)) .
\end{gather*}
$$

Note: Here $\langle N\rangle=\langle n\rangle$ because the system has only one single mode.

## - Fermi Energy

Metal phase is formed by many (weakly interacting) electrons that partially fill a band. The band structure (near the $\Gamma$ point) can be described by the quadratic dispersion

$$
\begin{equation*}
\epsilon_{k}=\frac{\hbar^{2} k^{2}}{2 m_{\mathrm{eff}}} \tag{285}
\end{equation*}
$$

- $m_{\text {eff }}$ - effective mass of electron in the crystal.
- $\boldsymbol{k}$ - quasi-momentum. Each $\boldsymbol{k}$ labels a mode $|\boldsymbol{k}\rangle$ that can be occupied by the electron. More precisely, the electron also carries spin, that can be in one of the two degenerated spin states, so the electronic mode is jointly labeled by $|\boldsymbol{k}, \sigma\rangle(\sigma=\uparrow, \downarrow)$.
The average total number of electron

$$
\begin{align*}
& N=2 \sum_{k} n_{\mathrm{F}}\left(\beta\left(\epsilon_{\boldsymbol{k}}-\mu\right)\right) \\
& =2 \frac{V}{(2 \pi)^{D}} \int d^{D} \boldsymbol{k} n_{\mathrm{F}}\left(\beta\left(\epsilon_{\boldsymbol{k}}-\mu\right)\right) . \tag{286}
\end{align*}
$$

- Prefactor of 2 accounts for the two degenerated spin states (the ways that electrons occupy both spins states are identical).
- $D$ - dimension of space.
- $V$ - volume of the system. Such that the discretization unit in the momentum space is $(2 \pi)^{D} / V$.

Define: Fermi energy (or Fermi level) $\epsilon_{\mathrm{F}}$ of the electronic system to be the chemical potential at zero temperature $T=0$ limit, given the number of electrons in the system.

- Fermi temperature $T_{\mathrm{F}}$

$$
\begin{equation*}
k_{B} T_{\mathrm{F}}=\epsilon_{\mathrm{F}} . \tag{287}
\end{equation*}
$$

- Fermi momentum $k_{\mathrm{F}}$

$$
\begin{equation*}
\frac{\hbar^{2} k_{\mathrm{F}}^{2}}{2 m_{\mathrm{eff}}}=\epsilon_{\mathrm{F}} . \tag{288}
\end{equation*}
$$

- Fermi velocity $v_{\mathrm{F}}$

$$
\begin{equation*}
v_{\mathrm{F}}=\frac{\hbar k_{\mathrm{F}}}{m_{\mathrm{eff}}}, \tag{289}
\end{equation*}
$$

hence $\epsilon_{\mathrm{F}}=\frac{1}{2} m_{\mathrm{eff}} v_{\mathrm{F}}^{2}$.

- Number of electrons at $T=0$. At zero temperature, the Fermi-Dirac distribution function reduces to a step function (written as $\Theta(x)=1$ for $x \geq 0$ and $\Theta(x)=0$ for $x<0$ ), such that Eq. (286) becomes

$$
\begin{aligned}
& N=2 \frac{V}{(2 \pi)^{D}} \int d^{D} \boldsymbol{k} \Theta\left(\epsilon_{\mathrm{F}}-\epsilon_{\boldsymbol{k}}\right), \\
& =2 \frac{V}{(2 \pi)^{D}} \int^{k<k_{\mathrm{F}}} d^{D} \boldsymbol{k}
\end{aligned}
$$

$$
\begin{aligned}
& =2 \frac{V}{(2 \pi)^{D}} \int^{k<k_{\mathrm{F}}} A_{D} k^{D-1} d k \\
& =2 \frac{V A_{D} k_{\mathrm{F}}^{D}}{D(2 \pi)^{D}}
\end{aligned}
$$

- $A_{D}=2 \pi^{D / 2} / \Gamma\left(\frac{D}{2}\right)$ - area of a ( $D-1$ )-dimensional unit sphere (in the $D$-dimensional space). $A_{D} k_{\mathrm{F}}^{D} / D$ is the volume of a ball of radius $k_{\mathrm{F}}$.
- At $T=0$, the electrons simply fill a ball in the momentum space of radius $k_{\mathrm{F}}$. The surface is the ball is called the Fermi surface.
- From Eq. (290), we can solve for the Fermi momentum $k_{\mathrm{F}}$

$$
\begin{equation*}
k_{\mathrm{F}}=2 \pi\left(\frac{D}{2 A_{D}} \frac{N}{V}\right)^{1 / D} \tag{291}
\end{equation*}
$$

or more explicitly (let $n=N / V$ )

$$
k_{\mathrm{F}}=\left\{\begin{array}{ll}
\pi n / 2 & D=1  \tag{292}\\
(2 \pi n)^{1 / 2} & D=2 \\
\left(3 \pi^{2} n\right)^{1 / 3} & D=3 \\
\ldots & \cdots
\end{array} .\right.
$$

- Correspondingly the Fermi energy

$$
\begin{equation*}
\epsilon_{\mathrm{F}}=\frac{(2 \pi)^{2} \hbar^{2}}{2 m_{\mathrm{eff}}}\left(\frac{D}{2 A_{D}} \frac{N}{V}\right)^{2 / D} . \tag{293}
\end{equation*}
$$

or more explicitly (let $n=N / V$ )

$$
\epsilon_{\mathrm{F}}=\frac{\hbar^{2}}{2 m_{\mathrm{eff}}}\left\{\begin{array}{ll}
(\pi n / 2)^{2} & D=1  \tag{294}\\
2 \pi n & D=2 \\
\left(3 \pi^{2} n\right)^{2 / 3} & D=3 \\
\ldots & \ldots
\end{array} .\right.
$$

- For typical metals, the Fermi energy is of the order $\epsilon_{\mathrm{F}} \sim 10 \mathrm{eV}$, which corresponds to a Fermi temperature of the order $T_{\mathrm{F}} \sim 10^{5} \mathrm{~K}$, much higher than the room temperature (also much higher than the melting temperature of metals).
Therefore, most electrons in the metal are deep in the Fermi sea and do not participate in thermodynamic or transport process. Such many-body state of electrons is also called degenerate Fermi gas, which also happens in other fermion systems as long as $T \ll T_{\mathrm{F}}$ (cold atomic gas $T_{\mathrm{F}} \sim 10^{-6} \mathrm{~K}$, white dwarf star $T_{\mathrm{F}} \sim 10^{9} \mathrm{~K}$ ).
- For typical metals, the Fermi velocity can be as large as $v_{\mathrm{F}} \sim 0.01 c$ ( $c$ - the speed of light). The high velocity of electron originated from the Pauli exclusion principle - all low momentum (low velocity) states are filled, and the active electrons around the Fermi surface has to move with high velocity.


## - Density of States

At finite temperature, the average total energy $E$ and total number $N$ of electrons is given by

$$
\begin{align*}
& E=2 \sum_{k} \epsilon_{k} n_{\mathrm{F}}\left(\beta\left(\epsilon_{k}-\mu\right)\right),  \tag{295}\\
& N=2 \sum_{k} n_{\mathrm{F}}\left(\beta\left(\epsilon_{k}-\mu\right)\right) .
\end{align*}
$$

The momentum summation can be converted to an energy integration

$$
\begin{equation*}
\sum_{k}=\frac{V}{(2 \pi)^{D}} \int d^{D} k=V \int d \epsilon_{k} g\left(\epsilon_{k}\right), \tag{296}
\end{equation*}
$$

by introducing the density of states

$$
\begin{equation*}
g(\epsilon)=\frac{D n}{4 \epsilon_{\mathrm{F}}}\left(\frac{\epsilon}{\epsilon_{\mathrm{F}}}\right)^{D / 2-1} \Theta(\epsilon), \tag{297}
\end{equation*}
$$

## Exc

12 Derive Eq. (297).


Using Eq. (296), Eq. (295) can be written as

$$
\begin{align*}
& E=2 V \int d \epsilon g(\epsilon) \epsilon n_{\mathrm{F}}(\beta(\epsilon-\mu)), \\
& N=2 V \int d \epsilon g(\epsilon) n_{\mathrm{F}}(\beta(\epsilon-\mu)) \tag{301}
\end{align*}
$$ calculate the density of state $g(\epsilon)$ in general $D$-dimensional space.

## - Low-Temperature Expansion

Both integrals in Eq. (301) are of the form

$$
\begin{equation*}
I=\int_{-\infty}^{\infty} d \epsilon f(\epsilon) n_{\mathrm{F}}(\beta(\epsilon-\mu)) . \tag{302}
\end{equation*}
$$

which admits the low-temperature expansion (Sommerfeld expansion) as $T \rightarrow 0$,

$$
\begin{equation*}
I=\int_{-\infty}^{\mu} d \epsilon f(\epsilon)+\sum_{n=1}^{\infty} \frac{2\left(k_{B} T\right)^{2 n}}{(2 n-1)!} \partial_{\mu}^{2 n-1} f(\mu) I_{2 n-1}, \tag{303}
\end{equation*}
$$

where the constants are given by

$$
\begin{equation*}
I_{2 n-1}=\int_{0}^{\infty} \frac{x^{2 n-1}}{e^{x}+1} d x=\left(1-\frac{2}{4^{n}}\right) \Gamma(2 n) \zeta(2 n) . \tag{304}
\end{equation*}
$$

## Exc

13
Derive Eq. (303) and Eq. (304).
The leading terms of the expansion reads

$$
\begin{equation*}
\int_{-\infty}^{\infty} d \epsilon f(\epsilon) n_{\mathrm{F}}(\beta(\epsilon-\mu))=\int_{-\infty}^{\mu} d \epsilon f(\epsilon)+\frac{\left(\pi k_{B} T\right)^{2}}{6} f^{\prime}(\mu)+\ldots \tag{309}
\end{equation*}
$$

Using Eq. (309), Eq. (301) can be evaluated to the leading order of $T$

$$
\begin{align*}
& E(\mu, T)=\frac{D}{D+2} N \epsilon_{\mathrm{F}}+2\left(\mu-\epsilon_{\mathrm{F}}\right) g\left(\epsilon_{\mathrm{F}}\right) \epsilon_{\mathrm{F}} V+\frac{\left(\pi k_{B} T\right)^{2}}{3}\left(g(\mu)+\mu g^{\prime}(\mu)\right) V+\ldots,  \tag{310}\\
& N(\mu, T)=N+2\left(\mu-\epsilon_{\mathrm{F}}\right) g\left(\epsilon_{\mathrm{F}}\right) V+\frac{\left(\pi k_{B} T\right)^{2}}{3} g^{\prime}(\mu) V+\ldots
\end{align*}
$$

## Exc <br> 14 <br> Derive Eq. (310).

The second equation (regarding $N$ ) in Eq. (310) implies that the chemical potential $\mu$ must vary with the temperature $T$ in the following manner to keep the particle number fixed

$$
\begin{equation*}
\mu=\epsilon_{\mathrm{F}}-\frac{\left(\pi k_{B} T\right)^{2}}{6} \frac{g^{\prime}\left(\epsilon_{\mathrm{F}}\right)}{g\left(\epsilon_{\mathrm{F}}\right)} . \tag{315}
\end{equation*}
$$

Substitute Eq. (315) into Eq. (310), we obtain the energy of the degenerate Fermi gas at low
temperature

$$
\begin{equation*}
E(T)=\frac{D}{D+2} N \epsilon_{\mathrm{F}}+\frac{\left(\pi k_{B} T\right)^{2}}{3} g\left(\epsilon_{\mathrm{F}}\right) V+\ldots \tag{316}
\end{equation*}
$$ potential is locked at zero $\mu(T)=0$ for any finite temperature.

## - Heat Capacity

- Heat capacity: the rate of energy $E$ change with respect to the temperature $T$

$$
\begin{equation*}
C_{V}=\frac{\partial E}{\partial T}=\frac{\pi^{2} k_{B}^{2} T}{3}\left(2 g\left(\epsilon_{\mathrm{F}}\right) V\right) \tag{317}
\end{equation*}
$$

For quadratic dispersion, the density of state $g(\epsilon)$ given in Eq. (297),

$$
\begin{equation*}
C_{V}=\frac{\pi^{2}}{3}\left(\frac{D N k_{B}}{2}\right)\left(\frac{T}{T_{\mathrm{F}}}\right) . \tag{318}
\end{equation*}
$$

- Specific heat: heat capacity per electron

$$
\begin{equation*}
c_{V}=\frac{C_{V}}{N}=\frac{\pi^{2} k_{B}^{2} T}{3} \frac{2 g\left(\epsilon_{\mathrm{F}}\right)}{n} \tag{319}
\end{equation*}
$$

For quadratic dispersion

$$
\begin{equation*}
c_{V}=\frac{\pi^{2}}{3}\left(\frac{D k_{B}}{2}\right)\left(\frac{T}{T_{\mathrm{F}}}\right) . \tag{320}
\end{equation*}
$$

- $D k_{B} / 2$ is the classical result for specific heat of a gas, where every atom in the gas can exchange energy with the heat bath. However, in metals, on those electrons near the Fermi surface can absorb/release energy, so the specific heat of such degenerate Fermi gas is smaller than the classical gas by a factor of $T / T_{\mathrm{F}}$, which is a tiny ratio $T / T_{\mathrm{F}} \sim 0.01$ in typical metals.
- At low-temperature, the specific heat of electrons in metals grows with temperature linearly $c_{V} \sim T$ (regardless of the spatial dimension $D$ of the system).
Further taken into account the specific heat of phonons, which scales as $c_{V} \sim T^{D}$, the total specific heat should take the form of

$$
\begin{equation*}
c_{V}=\gamma T+\alpha T^{D} \tag{321}
\end{equation*}
$$

for $D$-dimensional metal at low-temperature.

HW 8

Show that the electronic contribution to the specific heat in a single-layer graphene scales as $c_{V} \sim T^{2}$ at low temperature. [Hint: consider the low-energy electrons in graphene as 2D Dirac fermions with linear dispersion.]

## - Charge Compressibility

- Charge compressibility (quantum capacitance): the rate of charge $Q$ changes with respect to the electric potential $U$

$$
\begin{equation*}
C_{Q}=\frac{\partial Q}{\partial U}=e^{2} \frac{\partial N}{\partial \mu} . \tag{322}
\end{equation*}
$$

- $e$ - electric charge of electron.
- In the presence of electric potential $U$, the electron chemical potential shifts by
$\mu \rightarrow \mu-e U$.
As a result the number of electron changes by
$N \rightarrow N+\frac{\partial N}{\partial \mu}(-e U)$,
and the total charge $Q=-e N$ changes by
$Q \rightarrow Q+e^{2} \frac{\partial N}{\partial \mu} U$.
- Using the result in Eq. (310),
$N(\mu, T)=N+2\left(\mu-\epsilon_{\mathrm{F}}\right) g\left(\epsilon_{\mathrm{F}}\right) V+\ldots$,
we have

$$
\begin{equation*}
\frac{\partial N}{\partial \mu}=2 g\left(\epsilon_{\mathrm{F}}\right) V . \tag{327}
\end{equation*}
$$

So the charge compressibility is given by

$$
\begin{equation*}
C_{Q}=e^{2} \frac{\partial N}{\partial \mu}=e^{2}\left(2 g\left(\epsilon_{\mathrm{F}}\right) V\right) \tag{328}
\end{equation*}
$$

For quadratic dispersion, the density of state $g(\epsilon)$ given in Eq. (297),

$$
\begin{equation*}
C_{Q}=\frac{e^{2} D N}{2 \epsilon_{\mathrm{F}}} \tag{329}
\end{equation*}
$$

- Specific charge compressibility

$$
\begin{equation*}
c_{Q}=\frac{C_{Q}}{N}=e^{2} \frac{2 g\left(\epsilon_{\mathrm{F}}\right)}{n} . \tag{330}
\end{equation*}
$$

For quadratic dispersion,

$$
\begin{equation*}
c_{Q}=\frac{e^{2} D}{2 \epsilon_{\mathrm{F}}} . \tag{331}
\end{equation*}
$$

## - Spin Susceptibility

- Spin susceptibility: the rate of magnetization $M$ changes with respect to the external magnetic field $B$

$$
\begin{equation*}
\chi=\frac{\partial M}{\partial B} \tag{332}
\end{equation*}
$$

- $\mu_{\mathrm{B}}=e \hbar /\left(2 m_{e}\right)$ - Bohr magneton, the magnetic moment carried by the electron.
- In the presence of a magnetic field $B$, the up-spin and down-spin electron energy split

$$
\begin{align*}
& \epsilon_{k, \uparrow}=\epsilon_{k}+\mu_{\mathrm{B}} B,  \tag{333}\\
& \epsilon_{k, \downarrow}=\epsilon_{\boldsymbol{k}}-\mu_{\mathrm{B}} B .
\end{align*}
$$

Magnetization (average magnetic moment per electron) responds to the magnetic field as

$$
\begin{align*}
& M=\mu_{\mathrm{B}} \frac{N_{\uparrow}-N_{\downarrow}}{N} \\
& =\frac{\mu_{\mathrm{B}}}{N}\left(\frac{\partial N_{\uparrow}}{\partial \mu_{\uparrow}}\left(\mu_{\mathrm{B}} B\right)-\frac{\partial N_{\downarrow}}{\partial \mu_{\downarrow}}\left(-\mu_{\mathrm{B}} B\right)\right) \\
& =\frac{\mu_{\mathrm{B}}^{2}}{N}\left(\frac{\partial N_{\uparrow}}{\partial \mu_{\uparrow}}+\frac{\partial N_{\downarrow}}{\partial \mu_{\downarrow}}\right) B  \tag{334}\\
& =\frac{\mu_{\mathrm{B}}^{2}}{N} \frac{\partial N}{\partial \mu} B .
\end{align*}
$$

So the spin susceptibility can be calculated as

$$
\begin{equation*}
\chi=\frac{\mu_{\mathrm{B}}^{2}}{N} \frac{\partial N}{\partial \mu}=\mu_{\mathrm{B}}^{2} \frac{2 g\left(\epsilon_{\mathrm{F}}\right)}{n} . \tag{335}
\end{equation*}
$$

For quadratic dispersion, the density of state $g(\epsilon)$ given in Eq. (297),

$$
\begin{equation*}
\chi=\frac{\mu_{\mathrm{B}}^{2} D}{2 \epsilon_{\mathrm{F}}} . \tag{336}
\end{equation*}
$$

This constant spin susceptibility of the electron gas is also called the Pauli susceptibility, which (partially) explains the paramagnetism of metal.

## - Wilson Ratio

Specific heat $c_{V}$, charge compressibility $c_{Q}$, and spin susceptibility $\chi$ are all proportional to $2 g\left(\epsilon_{\mathrm{F}}\right) / n$ :

$$
\begin{aligned}
& c_{V}=\frac{\pi^{2} k_{B}^{2} T}{3} \frac{2 g\left(\epsilon_{\mathrm{F}}\right)}{n}, \\
& c_{Q}=e^{2} \frac{2 g\left(\epsilon_{\mathrm{F}}\right)}{n}, \\
& \chi=\mu_{\mathrm{B}}^{2} \frac{2 g\left(\epsilon_{\mathrm{F}}\right)}{n} .
\end{aligned}
$$

By taking ratios among them, the non-universal property $2 g\left(\epsilon_{\mathrm{F}}\right) / n$ can be canceled. The resulting universal ratio is called the Wilson ratio,

$$
\begin{equation*}
R_{W}=\frac{c_{Q} T}{c_{V}} \frac{\pi^{2} k_{B}^{2}}{3 e^{2}}=\frac{\chi T}{c_{V}} \frac{\pi^{2} k_{B}^{2}}{3 \mu_{\mathrm{B}}^{2}}=1 . \tag{338}
\end{equation*}
$$

- For non-interacting electrons, the Wilson ratio should be 1, which is expected to hold for typical metals.
- Deviation of the Wilson ratio from unity signifies the interaction effect between electrons is important in the material.


## - Transport Properties

## - Boltzmann Transport

Transport properties concern how metal conduct electricity and heat. In order to generate electric/heat current in the system, the electrons must deviate from their equilibrium distribution.

Boltzmann transport theory is a semiclassical theory for near-equilibrium electrons. The basic quantity of interest is the distribution function $f(\boldsymbol{x}, \boldsymbol{k}, t)$ of electron in the phase space ( $\boldsymbol{x}, \boldsymbol{k}$ ) as a function of time $t$.

- Equilibrium distribution. Without external perturbations, electrons relax to the equilibrium distribution

$$
\begin{equation*}
f_{\mathrm{eq}}(\boldsymbol{x}, \boldsymbol{k})=n_{\mathrm{F}}\left(\beta\left(\epsilon_{\boldsymbol{k}}-\mu\right)\right)=\frac{1}{\boldsymbol{e}^{\beta\left(\epsilon_{k}-\mu\right)}+1} . \tag{339}
\end{equation*}
$$

At the low-temperature limit $(T \rightarrow 0)$,

$$
\begin{align*}
& f_{\mathrm{eq}}(\boldsymbol{x}, \boldsymbol{k})=\Theta\left(\epsilon_{\mathrm{F}}-\epsilon_{k}\right) \\
& \Rightarrow \frac{\partial f}{\partial \epsilon_{k}}=-\delta\left(\epsilon_{\mathrm{F}}-\epsilon_{k}\right) . \tag{340}
\end{align*}
$$

- Relaxation of near equilibrium distribution. If $f$ deviated from $f_{\text {eq }}$, it will relax to $f_{\text {eq }}$ in a characteristic time scale $\tau$, called the relaxation time,

$$
\begin{equation*}
f(t)=f_{\mathrm{eq}}+\left(f(0)-f_{\mathrm{eq}}\right) e^{-t / \tau} . \tag{341}
\end{equation*}
$$

The relaxation dynamics can be described by the following differential equation

$$
\begin{equation*}
\frac{d f}{d t}=-\frac{f-f_{\mathrm{eq}}}{\tau} . \tag{342}
\end{equation*}
$$

- On the other hand, by the chain rule of differentiation

$$
\begin{equation*}
\frac{d f}{d t}=\frac{\partial f}{\partial t}+\frac{\partial f}{\partial \boldsymbol{x}} \cdot \frac{d \boldsymbol{x}}{d t}+\frac{\partial f}{\partial \boldsymbol{k}} \cdot \frac{d \boldsymbol{k}}{d t} . \tag{343}
\end{equation*}
$$

By semiclassical equation of motion

$$
\begin{align*}
& \frac{d \boldsymbol{x}}{d t}=\boldsymbol{v}_{k}=\frac{1}{\hbar} \partial_{k} \epsilon_{k},  \tag{344}\\
& \frac{d k}{d t}=\frac{1}{\hbar} \boldsymbol{F},
\end{align*}
$$

- $\boldsymbol{v}_{\boldsymbol{k}}$ - group velocity of the electron at momentum $\boldsymbol{k}$,
- $\boldsymbol{F}$ - external force acting on the electron.

Eq. (343) can be written as

$$
\begin{equation*}
\frac{d f}{d t}=\partial_{t} f+\boldsymbol{v}_{k} \cdot \partial_{x} f+\frac{1}{\hbar} \boldsymbol{F} \cdot \partial_{k} f . \tag{345}
\end{equation*}
$$

Combine Eq. (342) and Eq. (345), we obtain the Boltzmann equation

$$
\begin{equation*}
\partial_{t} f+\boldsymbol{v}_{k} \cdot \partial_{x} f+\frac{1}{\hbar} \boldsymbol{F} \cdot \partial_{k} f=-\frac{f-f_{\mathrm{eq}}}{\tau} . \tag{346}
\end{equation*}
$$

The stationary solution is defined to be the solution that $\partial f / \partial t=0$, which is given by

$$
\begin{equation*}
\boldsymbol{v}_{k} \cdot \partial_{x} f+\frac{1}{\hbar} \boldsymbol{F} \cdot \partial_{k} f=-\frac{f-f_{\mathrm{eq}}}{\tau} . \tag{347}
\end{equation*}
$$

## - Electrical Conductivity

Metal can conduct electricity in the presence of electric field $\boldsymbol{E}$. Electrons experience an external force

$$
\begin{equation*}
\boldsymbol{F}=-e \boldsymbol{E} \tag{348}
\end{equation*}
$$

Stationary solution should be given by Eq. (347)

$$
\begin{equation*}
-\frac{e}{\hbar} \boldsymbol{E} \cdot \partial_{k} f=-\frac{f-f_{\mathrm{eq}}}{\tau}, \tag{349}
\end{equation*}
$$

or written as a self-consistent equation

$$
\begin{equation*}
f=f_{\mathrm{eq}}+\frac{e \tau}{\hbar} \boldsymbol{E} \cdot \partial_{k} f . \tag{350}
\end{equation*}
$$

Assuming $f$ is close to $f_{\text {eq }}$, we can take $f \simeq f_{\text {eq }}$ as an initial approximation, and substitute it to Eq. (350) iteratively to find the self-consistent solution.

- To the first order in $\boldsymbol{E}$ (linear response),

$$
\begin{align*}
f & \simeq f_{\mathrm{eq}}+\frac{e \tau}{\hbar} \boldsymbol{E} \cdot \partial_{k} f_{\mathrm{eq}}  \tag{351}\\
& =f_{\mathrm{eq}}+e \boldsymbol{\tau} \boldsymbol{E} \cdot \boldsymbol{v}_{\boldsymbol{k}} \partial_{\epsilon} f_{\mathrm{eq}} .
\end{align*}
$$

- $f$ is deviated from $f_{\text {eq }}$. The main effect is to shift the Fermi sea in the momentum space by the amount of $-(e \tau / \hbar) \boldsymbol{E}$.


This can induced an electric current density

$$
\begin{align*}
\boldsymbol{J} & =-2 e \int \frac{d^{D} \boldsymbol{k}}{(2 \pi)^{D}} \boldsymbol{v}_{k} f  \tag{352}\\
& =-2 e \int \frac{d^{D} \boldsymbol{k}}{(2 \pi)^{D}} \boldsymbol{v}_{k} f_{\mathrm{eq}}-2 e^{2} \tau \int \frac{d^{D} \boldsymbol{k}}{(2 \pi)^{D}} \boldsymbol{v}_{\boldsymbol{k}} \boldsymbol{E} \cdot \boldsymbol{v}_{\boldsymbol{k}} \partial_{\epsilon} f_{\mathrm{eq}} .
\end{align*}
$$

- The prefactor 2 comes from the spin degeneracy
- The first term will vanish because there is no current when the system is at equilibrium.
- Switch the integral from the momentum space to the energy domain

$$
\begin{align*}
\boldsymbol{J} & =-2 e^{2} \boldsymbol{\tau} \int d \epsilon_{\boldsymbol{k}} g\left(\epsilon_{k}\right) \boldsymbol{v}_{\boldsymbol{k}} \boldsymbol{E} \cdot \boldsymbol{v}_{\boldsymbol{k}} \partial_{\epsilon} f_{\mathrm{eq}} \\
& =-\frac{2 e^{2} \boldsymbol{\tau} v_{F}^{2}}{3} \boldsymbol{E} \int d \epsilon g(\epsilon) \partial_{\epsilon} f_{\mathrm{eq}} . \tag{353}
\end{align*}
$$

The integral admits the following low-temperature expansion

$$
\begin{equation*}
\int d \epsilon g(\epsilon) \partial_{\epsilon} f_{\mathrm{eq}}=-g(\mu)-\frac{\pi^{2}}{6} \frac{\partial_{\mu}^{2} g(\mu)}{\beta^{2}}+\ldots \tag{354}
\end{equation*}
$$

## Exc

15
Derive Eq. (354).
Take the low-temperature limit and use $\mu=\epsilon_{\mathrm{F}}$ as $T \rightarrow 0$,

$$
\begin{equation*}
\boldsymbol{J}=\frac{2 e^{2} \tau v_{\mathrm{F}}^{2}}{3} g\left(\epsilon_{\mathrm{F}}\right) \boldsymbol{E} . \tag{359}
\end{equation*}
$$

The electrical conductivity $\sigma$ is defined via

$$
\begin{equation*}
\boldsymbol{J}=\sigma \boldsymbol{E} . \tag{360}
\end{equation*}
$$

Compare with Eq. (359), we can identify

$$
\begin{equation*}
\sigma=\frac{2 e^{2} \tau v_{\mathrm{F}}^{2}}{3} g\left(\epsilon_{\mathrm{F}}\right) . \tag{361}
\end{equation*}
$$

Using the density of state $g(\epsilon)$ given in Eq. (297),

$$
\begin{equation*}
\sigma=\frac{D}{3} \frac{e^{2} n \tau}{m_{\mathrm{eff}}} \tag{362}
\end{equation*}
$$

## - Thermal Conductivity

Metal can conduct heat in the presence of temperature gradient $\partial_{x} T$ (heat will flow from the high temperature side to the low temperature side). The temperature gradient enters the Boltzmann equation by creating a spatial gradient of the distribution function

$$
\begin{equation*}
\partial_{x} f=\partial_{T} f \partial_{x} T \tag{363}
\end{equation*}
$$

Stationary solution should be given by Eq. (347)

$$
\begin{equation*}
\boldsymbol{v}_{\boldsymbol{k}} \cdot \partial_{x} T \partial_{T} f=-\frac{f-f_{\mathrm{eq}}}{\tau}, \tag{364}
\end{equation*}
$$

or written as a self-consistent equation

$$
\begin{equation*}
f=f_{\mathrm{eq}}-\tau \boldsymbol{v}_{k} \cdot \partial_{x} T \partial_{T} f . \tag{365}
\end{equation*}
$$

Again, solving the self-consistent equation iteratively, starting from $f \simeq f_{\text {eq }}$.

- To the first order in $\partial_{x} T$ (linear response),

$$
\begin{equation*}
f \simeq f_{\mathrm{eq}}-\tau \boldsymbol{v}_{\boldsymbol{k}} \cdot \partial_{\boldsymbol{x}} T \partial_{T} f_{\mathrm{eq}} . \tag{366}
\end{equation*}
$$

Given $f_{\text {eq }}=\left(e^{(\epsilon-\mu) / T}+1\right)^{-1}, \partial_{T} f_{\text {eq }}$ and $\partial_{\epsilon} f_{\text {eq }}$ are related by

$$
\begin{equation*}
\partial_{T} f_{\mathrm{eq}}=-\frac{\epsilon-\mu}{T} \partial_{\epsilon} f_{\mathrm{eq}}, \tag{367}
\end{equation*}
$$

therefore

$$
\begin{equation*}
f \simeq f_{\mathrm{eq}}+\frac{\epsilon_{k}-\mu}{T} \tau \boldsymbol{v}_{k} \cdot \partial_{x} T \partial_{\epsilon} f_{\mathrm{eq}} . \tag{368}
\end{equation*}
$$

This can induced an energy current density

$$
\begin{align*}
& \boldsymbol{J}_{Q}=2 \int \frac{d^{D} \boldsymbol{k}}{(2 \pi)^{D}}\left(\epsilon_{\boldsymbol{k}}-\mu\right) \boldsymbol{v}_{\boldsymbol{k}} f \\
& =2 \int \frac{d^{D} \boldsymbol{k}}{(2 \pi)^{D}}\left(\epsilon_{\boldsymbol{k}}-\mu\right) \boldsymbol{v}_{\boldsymbol{k}} f_{\mathrm{eq}}+2 \int \frac{d^{D} \boldsymbol{k}}{(2 \pi)^{D}} \frac{\left(\epsilon_{\boldsymbol{k}}-\mu\right)^{2} \boldsymbol{\tau}}{T} \boldsymbol{v}_{\boldsymbol{k}} \boldsymbol{v}_{\boldsymbol{k}} \cdot \partial_{x} T \partial_{\epsilon} f_{\mathrm{eq}} . \tag{369}
\end{align*}
$$

- The prefactor 2 comes from the spin degeneracy
- The first term will vanish because there is no current when the system is at equilibrium.
- Switch the integral from the momentum space to the energy domain

$$
\begin{align*}
& \boldsymbol{J}_{Q}=\frac{2 \tau}{T} \int \frac{d^{D} \boldsymbol{k}}{(2 \pi)^{D}}\left(\epsilon_{k}-\mu\right)^{2} \boldsymbol{v}_{k} \boldsymbol{v}_{\boldsymbol{k}} \cdot \partial_{x} T \partial_{\epsilon} f_{\mathrm{eq}} \\
& =\frac{2 \tau}{T} \int d \epsilon_{\boldsymbol{k}} g\left(\epsilon_{k}\right)\left(\epsilon_{k}-\mu\right)^{2} \boldsymbol{v}_{\boldsymbol{k}} \boldsymbol{v}_{k} \cdot \partial_{x} T \partial_{\epsilon} f_{\mathrm{eq}}  \tag{370}\\
& =\frac{2 \tau v_{\mathrm{F}}^{2}}{3} \frac{\partial_{x} T}{T} \int d \epsilon g(\epsilon)(\epsilon-\mu)^{2} \partial_{\epsilon} f_{\mathrm{eq}} .
\end{align*}
$$

Use the low-temperature expansion in Eq. (354)

$$
\begin{equation*}
\int d \epsilon g(\epsilon)(\epsilon-\mu)^{2} \partial_{\epsilon} f_{\mathrm{eq}}=-\frac{\pi^{2}}{3} \frac{g(\mu)}{\beta^{2}}+\ldots \tag{371}
\end{equation*}
$$

therefore

$$
\begin{equation*}
\boldsymbol{J}_{Q}=-\frac{2 \tau v_{\mathrm{F}}^{2}}{3} g\left(\epsilon_{\mathrm{F}}\right) \frac{\pi^{2} k_{B}^{2} T}{3} \partial_{x} T . \tag{372}
\end{equation*}
$$

The thermal conductivity $\kappa$ is defined via

$$
\begin{equation*}
\boldsymbol{J}_{Q}=-\kappa \partial_{x} T \tag{373}
\end{equation*}
$$

Compare with Eq. (372), we can identify

$$
\begin{align*}
\kappa & =\frac{2 \tau v_{\mathrm{F}}^{2}}{3} g\left(\epsilon_{\mathrm{F}}\right) \frac{\pi^{2} k_{B}^{2} T}{3} \\
& =\frac{\pi^{2} k_{B}^{2}}{3 e^{2}} \sigma T  \tag{374}\\
& =\frac{D}{3} \frac{\pi^{2} k_{B}^{2} n \tau}{3 m_{\mathrm{eff}}} T,
\end{align*}
$$

where $\sigma$ is the electrical conductivity given in Eq. (361).

## - Lorenz Number

Eq. (374) reveals a proportionality between the thermal conductivity and the electrical conductivity, such that the ratio

$$
\begin{equation*}
L \equiv \frac{\kappa}{\sigma T}=\frac{\pi^{2}}{3}\left(\frac{k_{B}}{e}\right)^{2} \approx 2.443 \times 10^{-8} \mathrm{~W} \cdot \Omega \cdot \mathrm{~K}^{-2}, \tag{375}
\end{equation*}
$$

is a universal constant, known as the Lorenz number.

| Material | $L \times 10^{8}$ |
| :---: | :---: |
| Sodium (Na) | 2.12 |
| Magnesium $(\mathrm{Mg})$ | 2.14 |


| Copper (Cu) | 2.20 |
| :---: | :---: |
| Lithium (Li) | 2.22 |
| Zinc (Zn) | 2.33 |
| Silver $(\mathrm{Ag})$ | 2.37 |
| Gold $(\mathrm{Au})$ | 2.40 |
| Cadmium $(\mathrm{Cd})$ | 2.43 |
| Lead $(\mathrm{Pb})$ | 2.56 |
| Platinum $(\mathrm{Pt})$ | 2.60 |
| Iron $(\mathrm{Fe})$ | 2.61 |
| Tungsten $(\mathrm{W})$ | 3.20 |
| Bismuth $(\mathrm{Bi})$ | 3.53 |

- The fact that many metals have roughly the same $\kappa /(\sigma T)$ ratio is also known as the Wiede-mann-Franz law.
- Significance deviation of the Lorenz number of this value is an indication of the importance of electron interaction in the material.


## Interacting Electrons

## - Interacting Two-Electron Systems

## - Warmup: Classical Interacting Particles

Consider two classical particles restricted in a 1D system, described by a pair of coordinates $\left(x_{1}, x_{2}\right)$.


- Suppose there is some uncertainty about the positions $\rightarrow$ should think about the probability distribution of the particles $p\left(x_{1}\right)$ and $p\left(x_{2}\right)$


Or more precisely, the joint probability distribution

$$
\begin{equation*}
p\left(x_{1}, x_{2}\right)=p\left(x_{1}\right) p\left(x_{2}\right) . \tag{376}
\end{equation*}
$$



- Suppose the interaction between the two particles is described by the interaction potential $U\left(x_{1}-x_{2}\right)$ (assuming translation symmetry and inversion symmetry), the average interaction energy is

$$
\begin{equation*}
E_{U}=\int d x_{1} d x_{2} U\left(x_{1}-x_{2}\right) p\left(x_{1}, x_{2}\right) . \tag{377}
\end{equation*}
$$

(illustration of the integrand)


## - Interacting Fermions

However, the classical probability description does not apply to quantum particles, such as fermions (electrons).

- First, fermions are identical particles. There is no way to distinguish which electron is the first/second one. This implies that the probability distribution must be invariant under the exchange of the two fermions, i.e.

$$
\begin{equation*}
p\left(x_{1}, x_{2}\right)=p\left(x_{2}, x_{1}\right) \tag{378}
\end{equation*}
$$

- Secondly, fermions are quantum particles. The probability $p\left(x_{1}, x_{2}\right)$ should be modeled by the underlying probability amplitude (the wave function) $\psi\left(x_{1}, x_{2}\right)$ as

$$
\begin{equation*}
p\left(x_{1}, x_{2}\right)=\left|\psi\left(x_{1}, x_{2}\right)\right|^{2} \tag{379}
\end{equation*}
$$

Then Eq. (378) requires

$$
\begin{equation*}
\left|\psi\left(x_{1}, x_{2}\right)\right|^{2}=\left|\psi\left(x_{2}, x_{1}\right)\right|^{2} \tag{380}
\end{equation*}
$$

There are two options

$$
\psi\left(x_{1}, x_{2}\right)= \begin{cases}+\psi\left(x_{2}, x_{1}\right) & \text { bosons }  \tag{381}\\ -\psi\left(x_{2}, x_{1}\right) & \text { fermions. }\end{cases}
$$

Definition: Bosons/Fermions are identical quantum particles, whose many-body wave functions are symmetric/antisymmetric under particle exchange.

Consider two fermions occupying $\psi_{A}(x)$ and $\psi_{B}(x)$ orbitals respectively, the two-body wave function must take the following form (to respect the fermion antisymmetry)

$$
\begin{equation*}
\psi\left(x_{1}, x_{2}\right)=\frac{1}{\sqrt{2}}\left(\psi_{A}\left(x_{1}\right) \psi_{B}\left(x_{2}\right)-\psi_{B}\left(x_{1}\right) \psi_{A}\left(x_{2}\right)\right) . \tag{382}
\end{equation*}
$$

- One can already see, if $\psi_{A}=\psi_{B}$ are the same state, the two-body wave function vanishes automatically $\Rightarrow$ Pauli exclusion principle: fermions can not double occupy the same state.
- Consider two localized orbitals

$$
\begin{align*}
& \psi_{A}(x) \propto \exp \left(-\frac{\left(x-x_{A}\right)^{2}}{2}\right),  \tag{383}\\
& \psi_{B}(x) \propto \exp \left(-\frac{\left(x-x_{B}\right)^{2}}{2}\right) .
\end{align*}
$$

The two-body wave function can be constructed by antisymmetrization.


- Probability distribution

$$
\begin{align*}
& p\left(x_{1}, x_{2}\right)=\left|\psi\left(x_{1}, x_{2}\right)\right|^{2} \\
&= \frac{1}{2}\left|\psi_{A}\left(x_{1}\right) \psi_{B}\left(x_{2}\right)-\psi_{B}\left(x_{1}\right) \psi_{A}\left(x_{2}\right)\right|^{2} \\
&= \frac{1}{2}\left(\left|\psi_{A}\left(x_{1}\right)\right|^{2}\left|\psi_{B}\left(x_{2}\right)\right|^{2}+\left|\psi_{B}\left(x_{1}\right)\right|^{2}\left|\psi_{A}\left(x_{2}\right)\right|^{2}\right)-  \tag{384}\\
& \frac{1}{2}\left(\psi_{A}^{*}\left(x_{1}\right) \psi_{B}^{*}\left(x_{2}\right) \psi_{B}\left(x_{1}\right) \psi_{A}\left(x_{2}\right)+\psi_{B}^{*}\left(x_{1}\right) \psi_{A}^{*}\left(x_{2}\right) \psi_{A}\left(x_{1}\right) \psi_{B}\left(x_{2}\right)\right),
\end{align*}
$$

which contains two contributions

$$
\begin{equation*}
p\left(x_{1}, x_{2}\right)=p_{\mathrm{cl}}\left(x_{1}, x_{2}\right)-p_{\mathrm{qu}}\left(x_{1}, x_{2}\right) \tag{385}
\end{equation*}
$$

- the classical part is just the symmetrized product distribution

$$
\begin{equation*}
p_{\mathrm{cl}}\left(x_{1}, x_{2}\right)=\frac{1}{2}\left(p_{A}\left(x_{1}\right) p_{B}\left(x_{2}\right)+p_{B}\left(x_{1}\right) p_{A}\left(x_{2}\right)\right) \tag{386}
\end{equation*}
$$

where $p_{A / B}(x)=\left|\psi_{A / B}(x)\right|^{2}$.

- the quantum part is a correction that originates from quantum interference between fermions

$$
\begin{equation*}
p_{\mathrm{qu}}\left(x_{1}, x_{2}\right)=\frac{1}{2}\left(\psi_{A}^{*}\left(x_{1}\right) \psi_{B}^{*}\left(x_{2}\right) \psi_{B}\left(x_{1}\right) \psi_{A}\left(x_{2}\right)+\psi_{B}^{*}\left(x_{1}\right) \psi_{A}^{*}\left(x_{2}\right) \psi_{A}\left(x_{1}\right) \psi_{B}\left(x_{2}\right)\right) . \tag{387}
\end{equation*}
$$


$x_{1}$

$x_{1}$

- The average interaction energy

$$
\begin{equation*}
E_{U}=\int d x_{1} d x_{2} U\left(x_{1}-x_{2}\right) p\left(x_{1}, x_{2}\right) \tag{388}
\end{equation*}
$$

will also contain two terms

$$
\begin{equation*}
E_{U}=E_{\text {Hart }}-E_{\text {Fock }}, \tag{389}
\end{equation*}
$$

- the Hartree energy (direct energy) from the classical contribution

$$
\begin{align*}
& E_{\text {Hart }}=\int d x_{1} d x_{2} U\left(x_{1}-x_{2}\right) p_{\mathrm{cl}}\left(x_{1}, x_{2}\right) \\
& =\int d x_{1} d x_{2} U\left(x_{1}-x_{2}\right)\left|\psi_{A}\left(x_{1}\right)\right|^{2}\left|\psi_{B}\left(x_{2}\right)\right|^{2} . \tag{390}
\end{align*}
$$

In terms of the Dirac notation

$$
\begin{equation*}
E_{\text {Hart }}=\left\langle\psi_{A} \psi_{B}\right| U\left|\psi_{A} \psi_{B}\right\rangle . \tag{391}
\end{equation*}
$$



- the Fock energy (exchange energy) from the quantum correction

$$
\begin{align*}
& E_{\text {Fock }}=\int d x_{1} d x_{2} U\left(x_{1}-x_{2}\right) p_{\mathrm{qu}}\left(x_{1}, x_{2}\right) \\
& =\int d x_{1} d x_{2} U\left(x_{1}-x_{2}\right) \psi_{A}^{*}\left(x_{1}\right) \psi_{B}^{*}\left(x_{2}\right) \psi_{B}\left(x_{1}\right) \psi_{A}\left(x_{2}\right) . \tag{392}
\end{align*}
$$

In terms of the Dirac notation

$$
\begin{equation*}
E_{\text {Fock }}=\left\langle\psi_{A} \psi_{B}\right| U\left|\psi_{B} \psi_{A}\right\rangle . \tag{393}
\end{equation*}
$$



## - Hartree-Fock Approximation

Hartree-Fock approximation is a variational approach to solve for the ground state of interacting fermion systems.

$$
\begin{equation*}
H=\sum_{i} \underbrace{\frac{\boldsymbol{p}_{i}^{2}}{2 m}+V\left(\boldsymbol{x}_{i}\right)}_{H_{0}}+\sum_{i \neq j} U\left(\boldsymbol{x}_{i}-\boldsymbol{x}_{j}\right) . \tag{394}
\end{equation*}
$$

- It assumes that the $N$-body ground state can be approximated by the state of $N$ fermions separately occupying $N$ single-particle orbitals.
- By optimizing the orbital wave functions to minimize the energy, one can estimate the ground state energy as well as the approximate ground state wave function.

For example, consider a two-body system $(N=2)$ in 1D

$$
\begin{equation*}
H=H_{0}\left(p_{1}, x_{1}\right)+H_{0}\left(p_{2}, x_{2}\right)+U\left(x_{1}-x_{2}\right) \tag{395}
\end{equation*}
$$

Two orthonormal orbitals will be introduced, denoted as $\psi_{A}(x)$ and $\psi_{B}(x)$, and the variational state is taken to be

$$
\begin{equation*}
\psi\left(x_{1}, x_{2}\right)=\frac{1}{\sqrt{2}}\left(\psi_{A}\left(x_{1}\right) \psi_{B}\left(x_{2}\right)-\psi_{B}\left(x_{1}\right) \psi_{A}\left(x_{2}\right)\right) . \tag{396}
\end{equation*}
$$

The energy expectation value is given by

$$
\begin{equation*}
\langle\psi| H|\psi\rangle=\left\langle\psi_{A}\right| H_{0}\left|\psi_{A}\right\rangle+\left\langle\psi_{B}\right| H_{0}\left|\psi_{B}\right\rangle+\underbrace{\left\langle\psi_{A} \psi_{B}\right| U\left|\psi_{A} \psi_{B}\right\rangle}_{\text {Hartree }}-\underbrace{\left\langle\psi_{A} \psi_{B}\right| U\left|\psi_{B} \psi_{A}\right\rangle}_{\text {Fock }} . \tag{397}
\end{equation*}
$$

where

- the $A$ orbital energy is (similar for $B$ orbital)

$$
\begin{equation*}
\left\langle\psi_{A}\right| H_{0}\left|\psi_{A}\right\rangle=\int d x \psi_{A}^{*}(x)\left(-\frac{\hbar^{2}}{2 m} \partial_{x}^{2}+V(x)\right) \psi_{A}(x) . \tag{398}
\end{equation*}
$$

- the Hartree energy

$$
\begin{equation*}
\left\langle\psi_{A} \psi_{B}\right| U\left|\psi_{A} \psi_{B}\right\rangle=\int d x_{1} d x_{2} U\left(x_{1}-x_{2}\right)\left|\psi_{A}\left(x_{1}\right)\right|^{2}\left|\psi_{B}\left(x_{2}\right)\right|^{2}, \tag{399}
\end{equation*}
$$

- the Fock energy

$$
\begin{equation*}
\left\langle\psi_{A} \psi_{B}\right| U\left|\psi_{B} \psi_{A}\right\rangle=\int d x_{1} d x_{2} U\left(x_{1}-x_{2}\right) \psi_{A}^{*}\left(x_{1}\right) \psi_{B}^{*}\left(x_{2}\right) \psi_{B}\left(x_{1}\right) \psi_{A}\left(x_{2}\right) . \tag{400}
\end{equation*}
$$

Objective: optimize the functions $\psi_{A}(x)$ and $\psi_{B}(x)$ to minimize $\langle\psi| H|\psi\rangle$.

- The minimal value of $\langle\psi| H|\psi\rangle$ provides an estimation of the ground state energy.
- The optimal orbitals can be used to construct the many-body state $\psi\left(x_{1}, x_{2}\right)$, which is a variational approximation of the ground state.


## - Two Electrons in a Box

Consider two (spinless) electrons confined in a 1 D box (infinite square potential $x \in[0,1]$ ) interacting with each other via an repulsive potential

$$
\begin{equation*}
U(x)=g \operatorname{sech}\left(\frac{x}{\xi}\right), \tag{401}
\end{equation*}
$$



- Non-interacting limit $(g=0)$ : the electrons will occupy the lowest two orbitals in the square well. The single-electron density distribution can be calculated from

$$
\begin{equation*}
\rho(x)=\int\left|\psi\left(x, x^{\prime}\right)\right|^{2} d x^{\prime}=\left|\psi_{A}(x)\right|^{2}+\left|\psi_{B}(x)\right|^{2} . \tag{402}
\end{equation*}
$$



- The electrons are repelled from the infinite walls $\Rightarrow$ density vanishes approaching both walls.
- The electrons do not want to stay with each other (Pauli exclusion) $\Rightarrow$ a small dip in the middle part of the density distribution.
- Strong-interacting limit $(g \rightarrow \infty)$ : the electrons will further repel each other $\Rightarrow$ a deeper suppress of density in the middle, breaking the distribution into two peaks.

- Two localized orbitals emerges. Each electron occupies one localized orbital, and does not want to travel to the other side of the box.
- For more electrons (and in higher dimensions), this will lead to crystallization of electrons $\Rightarrow$ Wigner crystal.


## - Quantum Origin of Magnetism

## - Exchange Interaction (Ferromagnetism)

The above discussion has not included the internal spin state of the electron. The many-body state of electrons must be totally antisymmetric upon exchanging electrons in the orbital and the spin Hilbert spaces jointly: if the spin state is already symmetric/antisymmetric, the orbital state must be antisymmetric/symmetric.

For two electrons, each carries spin- $1 / 2$ (two states $|\uparrow\rangle$ and $|\downarrow\rangle$ )

- Antisymmetric spin state $\rightarrow$ spin singlet state $(s=0)$
$s m_{s}$
$\begin{array}{llll}0 & 0 & \frac{1}{\sqrt{2}}(|\uparrow \downarrow\rangle-|\downarrow \uparrow\rangle) .\end{array}$
Spins are anti-aligned as $\left\langle\boldsymbol{S}_{1} \cdot \boldsymbol{S}_{2}\right\rangle=-3 \hbar^{2} / 4<0 \Rightarrow$ antiferromagnetic.
- Symmetric spin states $\rightarrow \boldsymbol{\operatorname { s p i n }}$ triplet states $(s=1)$
$s m_{s}$
$1+1 \quad|\uparrow \uparrow\rangle$
$10 \quad \frac{1}{\sqrt{2}}(|\uparrow \downarrow\rangle+|\downarrow \uparrow\rangle)$
$1-1 \quad|\downarrow \downarrow\rangle$
Spins are aligned as $\left\langle\boldsymbol{S}_{1} \cdot \boldsymbol{S}_{2}\right\rangle=\hbar^{2} / 4>0 \Rightarrow$ ferromagnetic.
Suppose there are two energetically-degenerated orbitals $\psi_{A}(x)$ and $\psi_{B}(x)$ to occupied, the electrons can be either of the following states:
- Orbital symmetric, Spin antisymmetric (antiferromagnetic)

$$
\begin{equation*}
\frac{1}{\sqrt{2}}\left(\left|\psi_{A} \psi_{B}\right\rangle+\left|\psi_{B} \psi_{A}\right\rangle\right) \frac{1}{\sqrt{2}}(|\uparrow \downarrow\rangle-|\downarrow \uparrow\rangle) \tag{405}
\end{equation*}
$$

$\rightarrow$ Interaction energy

$$
\begin{equation*}
E_{U}=\left\langle\psi_{A} \psi_{B}\right| U\left|\psi_{A} \psi_{B}\right\rangle+\left\langle\psi_{A} \psi_{B}\right| U\left|\psi_{B} \psi_{A}\right\rangle . \tag{406}
\end{equation*}
$$

- Orbital antisymmetric, Spin symmetric (ferromagnetic)

$$
\begin{equation*}
\frac{1}{\sqrt{2}}\left(\left|\psi_{A} \psi_{B}\right\rangle-\left|\psi_{B} \psi_{A}\right\rangle\right) \frac{1}{\sqrt{2}}(|\uparrow \downarrow\rangle+|\downarrow \uparrow\rangle) \tag{407}
\end{equation*}
$$

$\rightarrow$ Interaction energy

$$
\begin{equation*}
E_{U}=\left\langle\psi_{A} \psi_{B}\right| U\left|\psi_{A} \psi_{B}\right\rangle-\left\langle\psi_{A} \psi_{B}\right| U\left|\psi_{B} \psi_{A}\right\rangle . \tag{408}
\end{equation*}
$$

Assuming the Fock energy is positive $\left\langle\psi_{A} \psi_{B}\right| U\left|\psi_{B} \psi_{A}\right\rangle>0$ (e.g. the repulsive Coulomb interaction), then the ferromagnetic state is lower in energy.

- Spin exchange interaction: the ferromagnetic spin-spin interaction between two electrons occupying two degenerated orbitals.
- This magnetic (spin) interaction originates from the quantum effect of the electric (charge) interaction (the exchange energy of Coulomb interaction). The fermionic nature of electron plays a key role in this mechanism.
[If the spin interaction was originated from the magnetic dipole interaction (electromagnetic force), the spins should tend to anti-align with each other, which makes it hard to explain the existence of ferromagnets.]
- Hund's rule: atomic orbitals in the same energy shell tend to be singly occupied by electrons of the same spin (to maximize the total spin).
This is a result of the spin exchange interaction between electrons on these orbitals.
- Magnetic interaction in molecules and solids. The spin exchange interaction is less effective between electrons from different atoms, because the overlap $\left\langle\psi_{A} \mid \psi_{B}\right\rangle$ between orbital wave functions is small, and the exchange interaction is also small in general. There is a competing effect in this case: both electrons tends to occupy the bonding orbital $\left|\psi_{A}\right\rangle+\left|\psi_{B}\right\rangle$ to lower the kinetic energy, then the spin must be anti-aligned due to the Pauli exclusion principle $\rightarrow$ leading to the antiferromagnetic interaction between electrons in a covalent bond.

| mechanism | type | origin |
| :---: | :---: | :---: |
| covalent bond | antiferro | kinetic energy |
| spin exchange | ferro | interaction energy |

It is quit subtle to determine whether electron spins on neighboring atoms want to be aligned or anti-aligned. Generally either behavior is possible.

## - Super-Exchange Interaction (Antiferromagnetism)

Hubbard model: tight binding model + on-site interaction (Hubbard interaction). It provides a good explanation for the antiferromagnetic interaction between electrons from neighboring atoms.

- Consider two sites (atoms) $A$ and $B$ adjacent to each other, with a total of two electrons.
- For each electron, there are four possible states

$$
\begin{equation*}
\left|A_{\uparrow}\right\rangle,\left|A_{\downarrow}\right\rangle,\left|B_{\uparrow}\right\rangle,\left|B_{\downarrow}\right\rangle . \tag{409}
\end{equation*}
$$

- Two electrons together has six possible states $\left(C_{4}^{2}=6\right)$

$$
\begin{align*}
& \left|A_{\uparrow} B_{\uparrow}\right\rangle=-\left|B_{\uparrow} A_{\uparrow}\right\rangle, \\
& \left|A_{\uparrow} B_{\downarrow}\right\rangle=-\left|B_{\downarrow} A_{\uparrow}\right\rangle, \\
& \left|A_{\downarrow} B_{\uparrow}\right\rangle=-\left|B_{\uparrow} A_{\downarrow}\right\rangle, \\
& \left|A_{\downarrow} B_{\downarrow}\right\rangle=-\left|B_{\downarrow} A_{\downarrow}\right\rangle,  \tag{410}\\
& \left|A_{\uparrow} A_{\downarrow}\right\rangle=-\left|A_{\downarrow} A_{\uparrow}\right\rangle, \\
& \left|B_{\uparrow} B_{\downarrow}\right\rangle=-\left|B_{\downarrow} B_{\uparrow}\right\rangle .
\end{align*}
$$

- Hopping term $H_{\text {hop }}$ turns a $A_{\uparrow}$ orbital to a $B_{\uparrow}$ orbital and vice versa, and similarly turns a $A_{\downarrow}$ orbital to a $B_{\downarrow}$ orbital and vice versa (electron hopping is independent of spin).
- For example, starting from $\left|A_{\uparrow} B_{\downarrow}\right\rangle$,

$$
\begin{align*}
& \left\langle A_{\uparrow} A_{\downarrow}\right| H_{\mathrm{hop}}\left|A_{\uparrow} B_{\downarrow}\right\rangle=-t,  \tag{411}\\
& \left\langle B_{\uparrow} B_{\downarrow}\right| H_{\mathrm{hop}}\left|A_{\uparrow} B_{\downarrow}\right\rangle=-t ;
\end{align*}
$$

starting from $\left|A_{\downarrow} B_{\uparrow}\right\rangle$,

$$
\begin{align*}
& \left\langle A_{\downarrow} A_{\uparrow}\right| H_{\mathrm{hop}}\left|A_{\downarrow} B_{\uparrow}\right\rangle=-t, \\
& \left\langle B_{\downarrow} B_{\uparrow}\right| H_{\mathrm{hop}}\left|A_{\downarrow} B_{\uparrow}\right\rangle=-t, \tag{412}
\end{align*}
$$

which can also be written as

$$
\begin{align*}
& \left\langle A_{\uparrow} A_{\downarrow}\right| H_{\mathrm{hop}}\left|A_{\downarrow} B_{\uparrow}\right\rangle=t,  \tag{413}\\
& \left\langle B_{\uparrow} B_{\downarrow}\right| H_{\mathrm{hop}}\left|A_{\downarrow} B_{\uparrow}\right\rangle=t,
\end{align*}
$$

given the basis relations in Eq. (410).

- If the electron spins are aligned, no hopping can occur. As hopping processes like

$$
\begin{align*}
\left|A_{\uparrow} B_{\uparrow}\right\rangle \rightarrow\left|B_{\uparrow} B_{\uparrow}\right\rangle & =0, \\
\left|A_{\uparrow} B_{\uparrow}\right\rangle \rightarrow\left|A_{\uparrow} A_{\uparrow}\right\rangle & =0, \tag{414}
\end{align*}
$$

are forbidden by the Pauli exclusion principle.

- The hopping Hamiltonian can be represented as a matrix

$$
H_{\text {hop }} \bumpeq\left(\begin{array}{cccc|cc}
0 & 0 & 0 & 0 & 0 & 0  \tag{415}\\
0 & 0 & 0 & 0 & -t & -t \\
0 & 0 & 0 & 0 & t & t \\
0 & 0 & 0 & 0 & 0 & 0 \\
\hline 0 & -t & t & 0 & 0 & 0 \\
0 & -t & t & 0 & 0 & 0
\end{array}\right) .
$$

- Interaction term $H_{\text {int }}$ gives energy penalty $U>0$ when two electrons are on the same site (such that they repel strongly)

$$
\begin{align*}
& \left\langle A_{\uparrow} A_{\downarrow}\right| H_{\mathrm{int}}\left|A_{\uparrow} A_{\downarrow}\right\rangle=U,  \tag{416}\\
& \left\langle B_{\uparrow} B_{\downarrow}\right| H_{\mathrm{int}}\left|B_{\uparrow} B_{\downarrow}\right\rangle=U,
\end{align*}
$$

which can be represented as a diagonal matrix for the last two states

$$
H_{\mathrm{int}} \bumpeq\left(\begin{array}{cccc|cc}
0 & 0 & 0 & 0 & 0 & 0  \tag{417}\\
0 & 0 & 0 & 0 & 0 & 0 \\
0 & 0 & 0 & 0 & 0 & 0 \\
0 & 0 & 0 & 0 & 0 & 0 \\
\hline 0 & 0 & 0 & 0 & U & 0 \\
0 & 0 & 0 & 0 & 0 & U
\end{array}\right)
$$

Put together the two-site Hubbard model Hamiltonian $H=H_{\text {hop }}+H_{\text {int }}$ can be written as

$$
H \bumpeq\left(\begin{array}{cccc|cc}
0 & 0 & 0 & 0 & 0 & 0  \tag{418}\\
0 & 0 & 0 & 0 & -t & -t \\
0 & 0 & 0 & 0 & t & t \\
0 & 0 & 0 & 0 & 0 & 0 \\
\hline 0 & -t & t & 0 & U & 0 \\
0 & -t & t & 0 & 0 & U
\end{array}\right) .
$$

- The spin-triplet states are eigenstates of $H$ of the eigen energy $E=0$

$$
\begin{array}{cc}
\text { energy } & \text { state } \\
0 & \left|A_{\uparrow} B_{\uparrow}\right\rangle \\
0 & \frac{1}{\sqrt{2}}\left(\left|A_{\uparrow} B_{\downarrow}\right\rangle+\left|A_{\downarrow} B_{\uparrow}\right\rangle\right)  \tag{419}\\
0 & \left|A_{\downarrow} B_{\downarrow}\right\rangle
\end{array} .
$$

- The following double occupied (anti-bonding) state is "dark" to hopping, which is also an eigenstate of $H$ of energy $E=U$,

$$
\begin{array}{cc}
\text { energy } & \text { state } \\
U & \frac{1}{\sqrt{2}}\left(\left|A_{\uparrow} A_{\downarrow}\right\rangle-\left|B_{\uparrow} B_{\downarrow}\right\rangle\right) \tag{420}
\end{array} .
$$

- The spin-singlet state and the double occupied (bonding) states can turn into each other via hopping,

$$
\begin{align*}
& |s\rangle=\frac{1}{\sqrt{2}}\left(\left|A_{\uparrow} B_{\downarrow}\right\rangle-\left|A_{\downarrow} B_{\uparrow}\right\rangle\right),  \tag{421}\\
& |d\rangle=\frac{1}{\sqrt{2}}\left(\left|A_{\uparrow} A_{\downarrow}\right\rangle+\left|B_{\uparrow} B_{\downarrow}\right\rangle\right) .
\end{align*}
$$

The Hamiltonian projected to the $|s\rangle,|d\rangle$ basis will be represented as

$$
H=\left(\begin{array}{cc}
0 & -2 t  \tag{422}\\
-2 t & U
\end{array}\right) .
$$

- Strong interaction limit $U \gg t$, the ground state $|s\rangle+O(t / U)$ is very close to the spin-singlet state $|s\rangle$ with the eigen energy
$E=-\frac{4 t^{2}}{U}$,
which is also the energy splitting between singlet and triplet state. In a spin model $H=J \boldsymbol{S}_{1} \cdot \boldsymbol{S}_{2}$, the energy splitting between the singlet $(E=-3 J / 4)$ and triplet $(E=J / 4)$ states is simply $J$.
Therefore Eq. (423) implies that the electronic system can be effectively viewed as a spin system in the strong interaction regime with an antiferromagnetic spin coupling

$$
\begin{equation*}
J=\frac{4 t^{2}}{U} \tag{424}
\end{equation*}
$$

which is also known as the super-exchange interaction.

- Weak interaction limit $U \ll t$, the ground state is

$$
\frac{1}{\sqrt{2}}(|s\rangle+|d\rangle)
$$

$$
\begin{aligned}
& =\frac{1}{2}\left(\left|A_{\uparrow} A_{\downarrow}\right\rangle+\left|A_{\uparrow} B_{\downarrow}\right\rangle-\left|A_{\downarrow} B_{\uparrow}\right\rangle+\left|B_{\uparrow} B_{\downarrow}\right\rangle\right) \\
& =\frac{1}{2}\left(\left|A_{\uparrow} A_{\downarrow}\right\rangle+\left|A_{\uparrow} B_{\downarrow}\right\rangle+\left|B_{\downarrow} A_{\uparrow}\right\rangle+\left|B_{\uparrow} B_{\downarrow}\right\rangle\right) \\
& =\frac{1}{\sqrt{2}}\left(\left|A_{\uparrow}\right\rangle+\left|B_{\uparrow}\right\rangle\right) \otimes \frac{1}{\sqrt{2}}\left(\left|A_{\downarrow}\right\rangle+\left|B_{\downarrow}\right\rangle\right),
\end{aligned}
$$

with eigen energy $-2 t$. This describes two electrons with opposite spins occupying the singleparticle bonding state together. Each electron gains the energy $t$ as the kinetic energy is reduced by hybridizing the two atomic orbitals.

- In both limits, the ground state is a spin-singlet state (antiferromagnetic). As the interaction is turned on it simply suppress the component of the double occupied state $|d\rangle$ in the ground state.


## - Instabilities of Metallic State

## - Itinerant Ferromagnetism

For free electron system, it is always energetically favorable to have the same number of up and down spins $\left(N_{\uparrow}=N_{\downarrow}\right)$, than to have the number differ.

- Because creating the spin imbalance (say $N_{\uparrow}>N_{\downarrow}$ ) corresponds to transferring some of the $\downarrow$ spin electrons from below the Fermi energy to $\uparrow$ spin electrons above the Fermi energy, which will always increase the energy.

- This can also be seen from the positive spin susceptibility $\chi$ of electron gas calculated in Eq. (335),

$$
\begin{equation*}
\chi=\frac{\partial M}{\partial B}=\mu_{\mathrm{B}}^{2} \frac{2 g\left(\epsilon_{\mathrm{F}}\right)}{n}, \tag{426}
\end{equation*}
$$

meaning that the total energy $E_{0}$ of a free electron system must grow with the magnetization $M$ as

$$
\begin{equation*}
\frac{E_{0}}{N}=\frac{1}{2 \chi} M^{2}-M B \tag{427}
\end{equation*}
$$

such that the minimal energy solution is always given by $M=\chi B$ (matching the paramagnetic behavior characterized by $\chi$ ).
This would predict that metals do not want to spontaneously magnetize in the absence of mag-
netic field. But how to explain the existence of ferromagnetic metals, like iron (Fe), nickel ( Ni ), cobalt (Co) etc.?

Electron interaction plays a central role in explaining the magnetism in materials.

- Consider a short-range interaction between electrons modeled by an interaction potential

$$
\begin{equation*}
U\left(\boldsymbol{x}-\boldsymbol{x}^{\prime}\right)=U_{0} \delta\left(\boldsymbol{x}-\boldsymbol{x}^{\prime}\right) \tag{428}
\end{equation*}
$$

Electron repels (assuming $g>0$ ) each other when they are in contact at a point. This mimics the behavior of (screened) Coulomb interaction.

- For electrons of the same spin,
- the Hartree energy

$$
\begin{align*}
& E_{\text {Hartree }}=\sum_{\epsilon_{k}, \epsilon_{k^{\prime}}<\mu_{\uparrow}}\left\langle\psi_{k \uparrow} \psi_{k^{\prime} \uparrow}\right| U\left|\psi_{k_{\uparrow} \uparrow} \psi_{k^{\prime} \uparrow}\right\rangle \\
& =U_{0} \sum_{\epsilon_{k}, k_{k}<\mu_{\uparrow}} \int d \boldsymbol{x}_{1} d \boldsymbol{x}_{2} \delta\left(\boldsymbol{x}_{1}-\boldsymbol{x}_{2}\right)\left|\psi_{k}\left(\boldsymbol{x}_{1}\right)\right|^{2}\left|\psi_{k^{\prime}}\left(\boldsymbol{x}_{2}\right)\right|^{2} \\
& =U_{0} \sum_{\epsilon_{k}, k_{k}<\mu_{\uparrow}} \int d \boldsymbol{x}\left|\psi_{\boldsymbol{k}}(\boldsymbol{x})\right|^{2}\left|\psi_{k^{\prime}}(\boldsymbol{x})\right|^{2}  \tag{429}\\
& =U_{0} \sum_{\epsilon_{k}, \epsilon_{k}<\mu_{\uparrow}} \frac{1}{V} \\
& =\frac{U_{0}, N_{\uparrow}^{2}}{V}
\end{align*}
$$

- the Fock energy is
$E_{\text {Fock }}=\sum_{\epsilon_{k}, k_{k}<\mu_{\uparrow}}\left\langle\psi_{k \uparrow} \psi_{k^{\uparrow} \uparrow}\right| U\left|\psi_{k^{\uparrow} \uparrow} \psi_{k \uparrow}\right\rangle$
$=U_{0} \sum_{\epsilon_{k},,_{k^{<}<\mu_{T}}} \int d \boldsymbol{x}_{1} d \boldsymbol{x}_{2} \delta\left(\boldsymbol{x}_{1}-\boldsymbol{x}_{2}\right) \psi_{\boldsymbol{k}}^{*}\left(\boldsymbol{x}_{1}\right) \psi_{k^{\prime}}^{*}\left(\boldsymbol{x}_{2}\right) \psi_{\boldsymbol{k}^{\prime}}\left(\boldsymbol{x}_{1}\right) \psi_{\boldsymbol{k}}\left(\boldsymbol{x}_{2}\right)$
$=U_{0} \sum_{\epsilon_{k}, \epsilon_{k^{\prime}}<\mu_{\uparrow}} \int d x\left|\psi_{k}(x)\right|^{2}\left|\psi_{k^{\prime}}(x)\right|^{2}$
$=U_{0} \sum_{\epsilon_{k}, \epsilon_{k}<\mu_{\uparrow}} \frac{1}{V}$
$=\frac{U_{0} N_{\uparrow}^{2}}{V}$,
- the Hartree energy is precisely canceled by the Fock energy, and the total interaction energy vanishes for same-spin electrons under short-range interaction,
$E_{U}=E_{\text {Hartree }}-E_{\text {Fock }}=0$.
This can be understood as a consequence of the Pauli exclusion principle that forbids the
same-spin electrons to come to the same point to interact.
- For electrons of opposite spins,
- the Hartree energy is similar

$$
\begin{align*}
& E_{\text {Hartree }}=\sum_{\epsilon_{k^{\prime}}<\mu_{\uparrow}} \sum_{\epsilon_{k^{\prime}}<\mu_{\downarrow}}\left\langle\psi_{k^{\prime} \uparrow} \psi_{k^{\prime} \downarrow}\right| U\left|\psi_{k_{\uparrow} \uparrow} \psi_{k^{\prime} \downarrow}\right\rangle \\
& =U_{0} \sum_{\epsilon_{k^{\prime}}<\mu_{\uparrow}} \sum_{\epsilon_{k^{\prime}}<\mu_{\downarrow}} \int d \boldsymbol{x}_{1} d \boldsymbol{x}_{2} \delta\left(\boldsymbol{x}_{1}-\boldsymbol{x}_{2}\right)\left|\psi_{\boldsymbol{k}}\left(\boldsymbol{x}_{1}\right)\right|^{2}\left|\psi_{k^{\prime}}\left(\boldsymbol{x}_{2}\right)\right|^{2} \\
& =U_{0} \sum_{\epsilon_{k}<\mu_{\uparrow}} \sum_{\epsilon_{k^{\prime}}<\mu_{\downarrow}} \int d \boldsymbol{x}\left|\psi_{k}(\boldsymbol{x})\right|^{2}\left|\psi_{k^{\prime}}(\boldsymbol{x})\right|^{2}  \tag{432}\\
& =U_{0} \sum_{\epsilon_{k^{\prime}}<\mu_{\uparrow}} \sum_{\epsilon_{k^{\prime}}<\mu_{\downarrow}} \frac{1}{V} \\
& =\frac{U_{0} N_{\uparrow} N_{\downarrow}}{V} .
\end{align*}
$$

- But there is no Fock energy contribution, because the orbital state can either be symmetric or antisymmetric (as the spin state can adjust accordingly), the two possibilities have opposite signed in front of their Fock energies, which cancel out.
- So the total interaction energy for opposite-spin electrons is

$$
\begin{equation*}
E_{U}=E_{\text {Hartree }}=\frac{U_{0} N_{\uparrow} N_{\downarrow}}{V} . \tag{433}
\end{equation*}
$$

Put together, the interaction energy of the electronic system is

$$
\begin{align*}
& E_{U}=\frac{U_{0} N_{\uparrow} N_{\downarrow}}{V} \\
& =\frac{U_{0}}{4 V}\left(\left(N_{\uparrow}+N_{\downarrow}\right)^{2}-\left(N_{\uparrow}-N_{\downarrow}\right)^{2}\right)  \tag{434}\\
& =\frac{U_{0} N^{2}}{4 V}\left(1-\left(\frac{M}{\mu_{\mathrm{B}}}\right)^{2}\right) .
\end{align*}
$$

- $N=N_{\uparrow}+N_{\downarrow}$ : total number of electrons,
- $M=\mu_{\mathrm{B}} \frac{N_{+}-N_{\mathrm{t}}}{N}$ : magnetization, average magnetic moment per electron.

The total energy $E=E_{0}+E_{U}$ of the system sums up contributions from both the kinetic (band) energy $E_{0}$ and the interaction energy $E_{U}$

$$
\begin{align*}
& \frac{E_{0}+E_{U}}{N}=\frac{1}{2 \chi} M^{2}-\frac{U_{0} n}{4 \mu_{\mathrm{B}}^{2}} M^{2}+\mathrm{const}  \tag{435}\\
& =\frac{n}{4 \mu_{\mathrm{B}}^{2}}\left(\frac{1}{g\left(\epsilon_{\mathrm{F}}\right)}-U_{0}\right) M^{2}+\mathrm{const}
\end{align*}
$$

The stability of the system relies on the sign of the quadratic coefficient in front of $M^{2}$.

- When $g\left(\epsilon_{\mathrm{F}}\right)^{-1}-U_{0}>0$, the energy minimum is at zero magnetization $M=0 . \Rightarrow$ The electronic system is stable in the spin-balanced state $\Rightarrow$ paramagnetic metal.
- When $g\left(\epsilon_{\mathrm{F}}\right)^{-1}-U_{0}<0$, the system can lower its energy by keep increasing the magnetization $M$ (until some higher-order effects set in to determine the saturation value of $M$ ). $\Rightarrow$ The spinbalanced electronic system is unstable towards spontaneous magnetization $\Rightarrow$ ferromagnetic metal.

Stoner Criterion: the condition for itinerant ferromagnetism to develop in electronic systems is

$$
\begin{equation*}
U_{0} g\left(\epsilon_{\mathrm{F}}\right)>1 \tag{436}
\end{equation*}
$$

i.e. the interaction must be repulsive and must be strong enough to overcome the kinetic energy loss.

## - Spin/Charge Density Wave

In the lattice system, electron interactions can lead to formation of density waves. Consider spin-1/2 electrons hopping on a 1D lattice, with on-site Hubbard interaction

$$
\begin{align*}
& H=H_{0}+H_{\mathrm{int}}, \\
& H_{0}=-t \sum_{i} \sum_{\sigma=\uparrow, \downarrow}\left(c_{i+1 \sigma}^{\dagger} c_{i \sigma}+\text { h.c. }\right),  \tag{437}\\
& H_{\mathrm{int}}=U \sum_{i} n_{i \uparrow} n_{i \downarrow} .
\end{align*}
$$



- At half filling, on average there is one electron per site (a site can at most host two electrons of $\uparrow$ and $\downarrow$ spins). Without interaction, the system is in the metallic phase.
- When $U>0$ (repulsive interaction), $\uparrow$ and $\downarrow$ spin electrons do not want to stay on the same site to avoid repulsive interaction $\Rightarrow$ different spins will spontaneously occupy alternative sites $\Rightarrow$ spin density wave (SDW).
- When $U<0$ (attractive interaction), $\uparrow$ and $\downarrow$ spin electrons wants to stay on the same site to gain attractive interaction $\Rightarrow$ electrons will spontaneously doubly occupy half of the sites and empty the other half alternatively $\Rightarrow$ charge density wave (CDW).
- Both SDW/CDW order spontaneously breaks the lattice translation symmetry and doubles the primitive unit cell.
To model the density wave state, consider a variational state as the ground state of a mean-field Hamiltonian

$$
\begin{equation*}
H_{\mathrm{MF}}=-\frac{u}{2} \sum_{i}(|i+1\rangle\langle i|+\text { h.c. })-v \sum_{i}(-1)^{i}|i\rangle\langle i| . \tag{438}
\end{equation*}
$$

- $u$ - hopping strength of the mean-field model, set to $u=1$ in the end ( $H_{\mathrm{MF}}$ can always be rescaled by an overall factor without affecting the variational ground state).
- $v$ - stagger potential, serves as the variational parameter, controls the ordering strength.

Take the two-site unit-cell, transform to the momentum space

$$
\begin{align*}
& |k, A\rangle=L^{-1 / 2} \sum_{i \in A} e^{i k x_{i}}|i\rangle, \\
& |k, B\rangle=L^{-1 / 2} \sum_{i \in B} e^{i k x_{i}}|i\rangle, \tag{439}
\end{align*}
$$

- $A$ sublattice: $i$ is even, $B$ sublattice: $i$ is odd.
- $L$ - number of unit cell (not using $N$ to avoid confusion with the total electron number).
- Site coordinate $x_{i}=i$ (unit cell volume $=2$ ).
- First Brillouin zone: $k \in[-\pi / 2, \pi / 2)$.

Focus on one spin species, the mean-field Hamiltonian reads

$$
\begin{equation*}
H_{\mathrm{MF}}=-\sum_{k}(u \cos k|k, A\rangle\langle k, B|+\text { h.c. })-v \sum_{k}(|k, A\rangle\langle k, A|-|k, B\rangle\langle k, B|), \tag{440}
\end{equation*}
$$

or in matrix representation as

$$
H \bumpeq \bigoplus_{k} H_{k}, H_{k} \bumpeq-\left(\begin{array}{cc}
v & u \cos k  \tag{441}\\
u \cos k & -v
\end{array}\right)
$$

- Band dispersion

$$
\begin{equation*}
\epsilon_{k, \pm}= \pm \sqrt{(u \cos k)^{2}+v^{2}} \tag{442}
\end{equation*}
$$

The stagger potential $v$ opens a gap, splitting spectrum into two bands. Half-filling the electronic system $\Rightarrow$ fully occupies the lower band.
Total mean-field energy for the spin species (at $T=0$ )

$$
\begin{align*}
& \left\langle H_{\mathrm{MF}}\right\rangle=\sum_{k \in \mathrm{BZ}} \epsilon_{k,-}=-\sum_{k \in \mathrm{BZ}} \sqrt{(u \cos k)^{2}+v^{2}} \\
& =-L \int_{-\pi / 2}^{\pi / 2} \frac{d k}{\pi} \sqrt{(u \cos k)^{2}+v^{2}} . \tag{443}
\end{align*}
$$

- Define the expected bonding strength (for single spin species)

$$
\begin{equation*}
\gamma=2\left\langle c_{i+1}^{\dagger} c_{i}+\text { h.c. }\right\rangle, \tag{444}
\end{equation*}
$$

It can be evaluated from

$$
\begin{equation*}
\left\langle\frac{\partial H_{\mathrm{MF}}}{\partial u}\right\rangle_{u=1}=-L \gamma, \tag{445}
\end{equation*}
$$

therefore

$$
\begin{aligned}
& \gamma=\int_{-\pi / 2}^{\pi / 2} \frac{d k}{\pi} \frac{\cos ^{2} k}{\sqrt{\cos ^{2} k+v^{2}}} .
\end{aligned}
$$

$$
\begin{aligned}
& v
\end{aligned}
$$

- Define the expected density imbalance (for single spin species)

$$
\begin{equation*}
\delta=\left\langle n_{A}\right\rangle-\left\langle n_{B}\right\rangle \tag{447}
\end{equation*}
$$

It can be evaluated from

$$
\begin{equation*}
\left\langle\frac{\partial H_{\mathrm{MF}}}{\partial v}\right\rangle_{u=1}=-L \delta, \tag{448}
\end{equation*}
$$

therefore

$$
\begin{equation*}
\delta=\int_{-\pi / 2}^{\pi / 2} \frac{d k}{\pi} \frac{v}{\sqrt{\cos ^{2} k+v^{2}}} . \tag{449}
\end{equation*}
$$


$v$
Given that $\left\langle n_{A}\right\rangle+\left\langle n_{B}\right\rangle=1$ (filling one band $\Leftrightarrow$ one fermion per unit cell),

$$
\begin{equation*}
\left\langle n_{A}\right\rangle=\frac{1+\delta}{2},\left\langle n_{B}\right\rangle=\frac{1-\delta}{2} . \tag{450}
\end{equation*}
$$

With these preparations,

- The expectation energy for the SDW state is

$$
\begin{align*}
& \frac{\langle H\rangle}{L}=-2 t \gamma+U\left(2\left\langle n_{A}\right\rangle\left\langle n_{B}\right\rangle\right)  \tag{451}\\
& =-2 t \gamma+\frac{U}{2}\left(1-\delta^{2}\right),
\end{align*}
$$

which has non-trivial minimum at $v \neq 0$ when $U>0$.


- The energy minimum is achieved at $\partial_{v}\langle H\rangle=0$ (excluding the $v=0$ solution), which is given by the mean-field equation

$$
\begin{equation*}
1-\frac{U}{2 t} \int_{-\pi / 2}^{\pi / 2} \frac{d k}{\pi} \frac{1}{\sqrt{\cos ^{2} k+v^{2}}}=0 \tag{452}
\end{equation*}
$$

Exc
Derive Eq. (452).

- For small $U / t$ (hence small $v$ ) the equation can be approximated by

$$
\begin{equation*}
1-\frac{U}{2 t} \frac{2}{\pi} \ln \left(\frac{4}{|v|}\right)=0 \tag{459}
\end{equation*}
$$

whose solution is

$$
\begin{equation*}
|v|=4 \exp \left(-\frac{t \pi}{U}\right) \tag{460}
\end{equation*}
$$

The SDW gap $|v|$ opens with the repulsive interaction $U$ non-perturbatively.


- Correspondingly, the SDW order parameter $\delta$ is also induced non-perturbatively

$$
\begin{equation*}
|\delta|=\frac{t}{2 U} \exp \left(-\frac{t \pi}{U}\right) . \tag{461}
\end{equation*}
$$

- The expectation energy for the CDW state is

$$
\begin{align*}
& \frac{\langle H\rangle}{L}=-2 t \gamma+U\left(\left\langle n_{A}\right\rangle^{2}+\left\langle n_{B}\right\rangle^{2}\right) \\
& =-2 t \gamma+\frac{U}{2}\left(1+\delta^{2}\right), \tag{462}
\end{align*}
$$

which has non-trivial minimum at $v \neq 0$ when $U<0$.


The energy minimum is achieved at $\partial_{v}\langle H\rangle=0$ (excluding the $v=0$ solution), which is given by the mean-field equation

$$
\begin{equation*}
1-\frac{(-U)}{2 t} \int_{-\pi / 2}^{\pi / 2} \frac{d k}{\pi} \frac{1}{\sqrt{\cos ^{2} k+v^{2}}}=0 \tag{463}
\end{equation*}
$$

- For small $U / t$ (hence small $v$ ) the equation can be approximated by

$$
\begin{equation*}
1-\frac{(-U)}{2 t} \frac{2}{\pi} \ln \left(\frac{4}{|v|}\right)=0 \tag{464}
\end{equation*}
$$

whose solution is

$$
\begin{equation*}
|v|=4 \exp \left(-\frac{t \pi}{(-U)}\right) . \tag{465}
\end{equation*}
$$

The CDW gap $|v|$ opens with the attractive interaction ( $-U$ ) non-perturbatively.

- Correspondingly, the CDW order parameter $\delta$ is also induced non-perturbatively.

$$
\begin{equation*}
|\delta|=\frac{t}{2(-U)} \exp \left(-\frac{t \pi}{(-U)}\right) . \tag{466}
\end{equation*}
$$

In conclusion, the 1D (half-filled) metallic state is unstable under interaction. Infinitesimal interaction (no matter repulsive or attractive) will trigger the development of density wave order that
spontaneously breaks the lattice translation symmetry. Its consequence can be observed by scattering experiments, that new satellite peaks will appear due to the scattering with spin/charge modulations.

The same phenomenon also happens in higher dimension, when the Fermi surface is nested.

- For example, half-filled square lattice hopping model has a square-shaped Fermi surface, where parallel edges coincide when shifted by the nesting momentum $\boldsymbol{Q}$.

- The phenomenon of two finite segments of the Fermi surface are connected by the same moment shift is called Fermi surface nesting. In this case, the Fermi surface has an instability towards SDW/CDW ordering under interaction. The density wave vector is set by the nesting momentum.
- Density wave order generally leads to gap opening on the Fermi surface. At the low temperature limit $(T=0)$, the gap size $\Delta$ scales with interaction strength $U$ as

$$
\begin{equation*}
\Delta \sim \exp \left(-\frac{1}{2 U g\left(\epsilon_{\mathrm{F}}\right)}\right) \tag{467}
\end{equation*}
$$

where $g\left(\epsilon_{\mathrm{F}}\right)$ is the Fermi surface density of state.

